

# **LI+ BATTERY CHARGER WITH WLED DRIVER AND CURRENT SHUNT MONITOR**

Check for Samples: [TPS65200](#)

## **FEATURES**

- Battery Switching Charger, WLED Driver, and Current Shunt Monitor in a Single Package
- BATTERY CHARGER**
- Charges Faster Than Linear Chargers
- High-Accuracy Voltage and Current Regulation
  - Input Current Regulation Accuracy:  $\pm 5\%$  (100 mA, 500 mA)
  - Charge Voltage Regulation Accuracy:  $\pm 0.5\%$  (25°C),  $\pm 1\%$  (0 - 125°C)
  - Charge Current Regulation Accuracy:  $\pm 5\%$
- Input Voltage Based Dynamic Power Management
- Bad Adaptor Detection and Rejection
- Safety Limit Register for Maximum Charge Voltage and Current Limiting
- High-Efficiency Mini-USB/AC Battery Charger for Single-Cell Li-Ion and Li-Polymer Battery Packs
- 20-V Absolute Maximum Input Voltage Rating
- 6.0-V Maximum Operating Input Voltage
- Built-In Input Current Sensing and Limiting
- Integrated Power FETs for Up to 1.25-A Charge Rate
- Programmable Charge Parameters through I<sup>2</sup>C Interface (up to 400 Kbps):
  - Input Current
  - Fast-Charge/Termination Current
  - Charge Voltage (3.5 V - 4.44 V)
  - Safety Timer
  - Termination Enable
- Synchronous Fixed-Frequency PWM Controller Operating at 3 MHz With 0% to 99.5% Duty Cycle

- Automatic High Impedance Mode for Low Power Consumption
- Safety Timer with Reset Control
- Reverse Leakage Protection Prevents Battery Drainage
- Thermal Regulation and Protection
- Input/Output Over Voltage Protection
- Status Output for Charging and Faults
- USB Friendly Boot-Up Sequence
- Automatic Charging
- Boost Mode Operation for USB OTG
  - Input Voltage Range (V<sub>SY</sub>): 2.5 V to 4.5 V
  - Output Voltage for V<sub>BUS</sub>: 5 V
- WLED DRIVER**
- 35-V Open LED Protection for up to 8 LEDs
- 200-mV Reference Voltage With  $\pm 2\%$  Accuracy
- Built-In Soft Start for WLED Boost
- Up to 90% Efficiency
- 2.5-V - 4.5-V Battery Voltage Range (Charger and Current Shunt Monitor)
- CURRENT SHUNT MONITOR**
- Fixed Gain of 25 V/V
- Input Referred Offset Voltage Less Than  $\pm 40 \mu\text{V}$  Typical Enables Use of Shunt Resistors as Low as 20 m $\Omega$
- Buffered Reference Voltage
- 2.5-V - 4.5-V Battery Voltage Range (Charger and Current Shunt monitor)
- PACKAGE**
- 36-Ball, 0.4-mm Pitch DSBGA Package
- 6-mm x 6-mm, 0.5-mm Pitch QFN

## **APPLICATIONS**

- Mobile Phones and Smart Phones
- MP3 Players
- Portable Navigation Devices
- Handheld Devices



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## DESCRIPTION

The TPS65200 integrates a high-efficiency, USB-friendly switch-mode charger with OTG support for single-cell Li-ion and Li-polymer batteries, D+D- detection, a 50-mA fixed-voltage LDO, a high-efficiency WLED boost converter, and high-accuracy current-shunt monitor into a single chip.

The charger features a synchronous 3-MHz PWM controller with integrated power MOSFETs, input current sensing and regulation, input-voltage dynamic power management, high-accuracy charge current and voltage regulation, and charge termination. It charges the battery in three phases: low-current pre-charge, constant current fast-charge, and constant voltage trickle-charge. The input current is automatically limited to the value set by the host. The charger can be configured to terminate charge based on user-selectable minimum current level and to automatically restart the charge cycle if the battery voltage falls below the recharge threshold. A safety timer with reset control provides a safety backup for I<sup>2</sup>C interface. The charger automatically enters sleep mode or high impedance mode when the input supply is removed. The charge status is reported to the host using the I<sup>2</sup>C interface and STAT pin. The D+D- detection circuit allows automatic detection of a USB wall-charger. If a wall-charger is detected the input current limit is automatically increased from 500 mA to 975 mA.

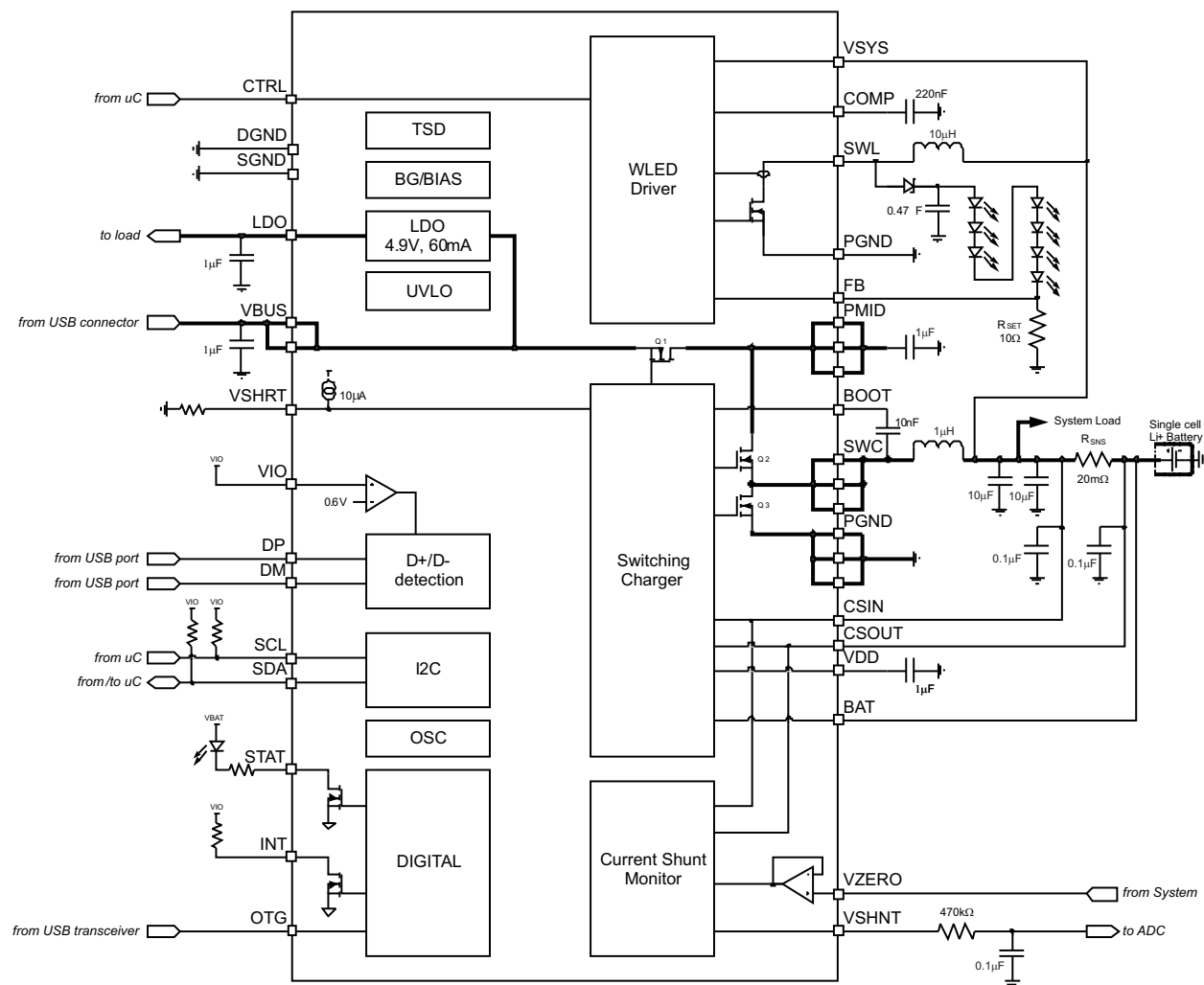
In OTG mode the PWM controller boosts the battery voltage to 5 V and provides up to 200-mA of current to the USB output. At very light loads the boost operates in burst mode to optimize efficiency. OTG mode can be enabled either through I<sup>2</sup>C interface or GPIO control.

The TPS65200 also provides a WLED boost converter with integrated 40-V switch FET, that drives up to 10 WLEDs in series. The boost converter runs at 600-kHz fixed switching frequency to reduce output ripple, improve conversion efficiency, and allows for the use of small external components. The default WLED current is set with a sense resistor, and the feedback voltage is regulated to 200 mV, as shown in the typical application. For brightness dimming, the feedback voltage can be changed through the I<sup>2</sup>C interface or by application of a PWM signal to the CTRL pin. In the latter case the feedback voltage is regulated down proportional to the PWM duty cycle (analog dimming) rather than pulsing the LED current to avoid audible noise on the output capacitor. For maximum protection, the device features integrated open LED protection that disables the TPS65200 to prevent the output from exceeding the absolute maximum ratings during open LED conditions.

A fixed-gain, high-accuracy current shunt monitor senses the voltage drop across an external, 20-mΩ sense resistor and provides an analog output voltage that is proportional to the charge/discharge current of the battery. The sense voltage is amplified by a factor of 25 and offset by V<sub>ZERO</sub>, an externally provided reference voltage. V<sub>ZERO</sub> is internally buffered to avoid loading of the reference source.

The TPS65200 comes in a tiny, 2.8-mm x 2.6-mm, 36-ball, 0.4-mm pitch die size ball grid array (DSBGA) or a 6-mm x 6-mm, 0.5-mm pitch QFN.

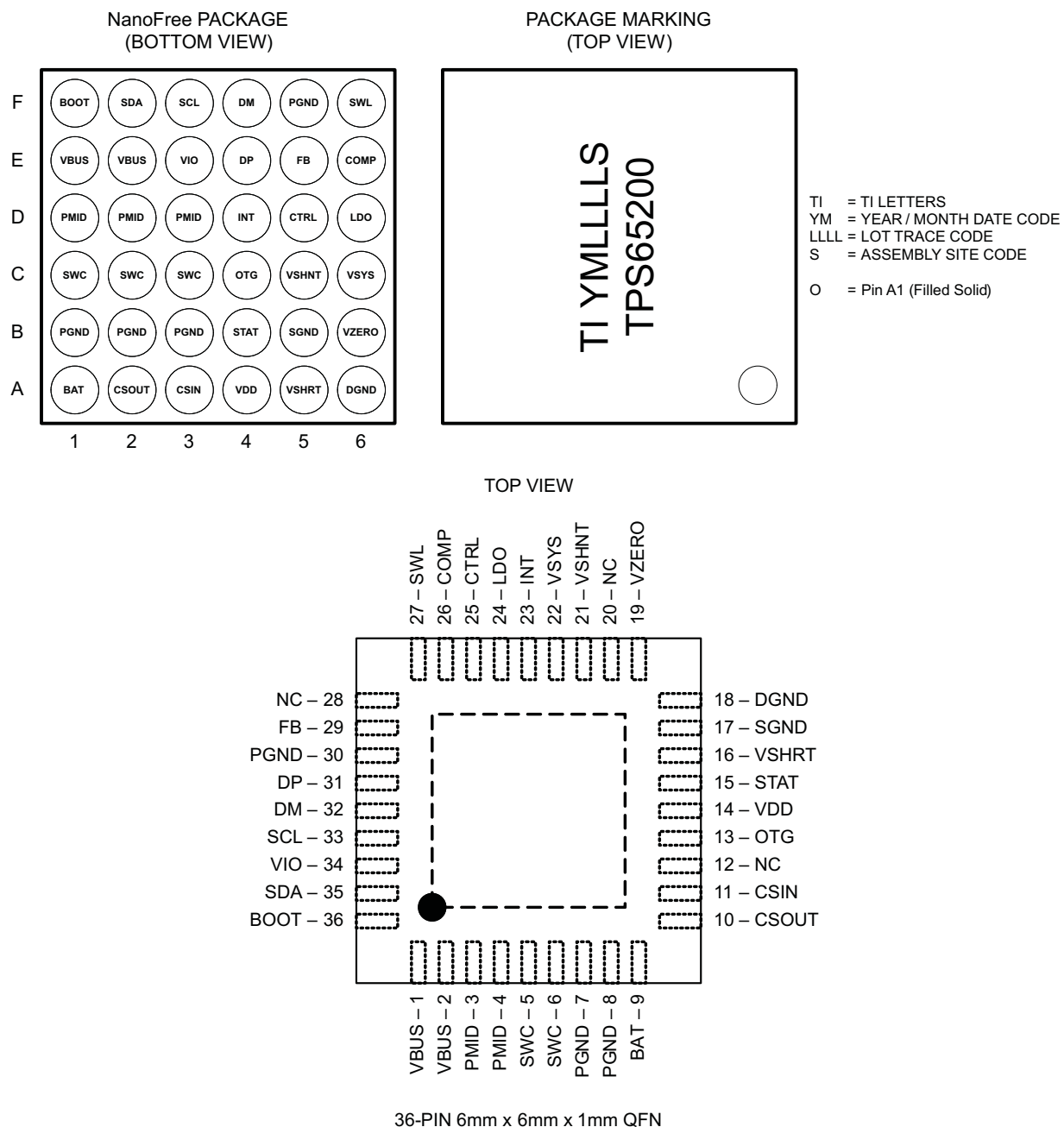
# **FUNCTIONAL BLOCK DIAGRAM**



## **ORDERING INFORMATION**

| T <sub>A</sub> | PACKAGE | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|----------------|---------|-----------------------|------------------|
| -40°C to 85°C  | DSBGA   | TPS65200YFFR          | TPS65200         |
|                | QFN     | TPS65200RHHR          | TPS65200         |

## PIN CONFIGURATION



| TERMINAL |                |       | I/O | DESCRIPTION                                                                                                                                                                                                                                                                                                                                      |
|----------|----------------|-------|-----|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME     | NO.            |       |     |                                                                                                                                                                                                                                                                                                                                                  |
|          | (DSBGA)        | (QFN) |     |                                                                                                                                                                                                                                                                                                                                                  |
| CSOUT    | A2             | 10    | I   | Charge current-sense input. Battery current is sensed via the voltage drop across an external sense resistor. A 0.1-μF ceramic capacitor to PGND is required.                                                                                                                                                                                    |
| VBUS     | E1, E2         | 1, 2  | I/O | Charger input voltage. Bypass it with a 1-μF ceramic capacitor from VBUS to PGND. It also provides power to the load in boost mode.                                                                                                                                                                                                              |
| BAT      | A1             | 9     | O   | Output of the linear charger and battery voltage sense. Connect the battery from this pin to ground.                                                                                                                                                                                                                                             |
| VSYS     | C6             | 22    | I   | Input supply for WLED driver and current shunt monitor                                                                                                                                                                                                                                                                                           |
| PMID     | D1, D2, D3     | 3, 4  | O   | Connection point between reverse blocking MOSFET and high-side switching MOSFET. Bypass it with a minimum of 1-μF capacitor from PMID to PGND. No other circuits are recommended to connect at PMID pin.                                                                                                                                         |
| SWC      | C1, C2, C3     | 5, 6  | O   | Internal switch to inductor connection (charger)                                                                                                                                                                                                                                                                                                 |
| BOOT     | F1             | 36    | O   | Boot-strapped capacitor for the high-side MOSFET gate driver. Connect a 10-nF ceramic capacitor (voltage rating above 10 V) from BOOST pin to SWC pin.                                                                                                                                                                                           |
| PGND     | B1, B2, B3, F5 | 7, 8  |     | Power ground                                                                                                                                                                                                                                                                                                                                     |
| CSIN     | A3             | 11    | I   | Charge current-sense input. Battery current is sensed via the voltage drop across an external sense resistor. A 0.1-μF ceramic capacitor to PGND is required.                                                                                                                                                                                    |
| SCL      | F3             | 33    | I   | I <sup>2</sup> C interface clock                                                                                                                                                                                                                                                                                                                 |
| SDA      | F2             | 35    | I/O | I <sup>2</sup> C interface data                                                                                                                                                                                                                                                                                                                  |
| STAT     | B4             | 15    | O   | Charge status pin. Pulled low when charge in progress. Open drain for other conditions. This pin can also be controlled through I <sup>2</sup> C register. STAT can be used to drive a LED or communicate with a host processor.                                                                                                                 |
| VDD      | A4             | 14    | O   | Internal supply for battery charger. Connect a 1-mF ceramic capacitor from this output to PGND. External load on VDD is not recommended.                                                                                                                                                                                                         |
| DP       | E4             | 31    | I   | USB port D+ input connection                                                                                                                                                                                                                                                                                                                     |
| DM       | F4             | 32    | I   | USB port D- input connection                                                                                                                                                                                                                                                                                                                     |
| LDO      | D6             | 24    | O   | LDO output. LDO is regulated to 4.9 V and drives 60-mA of current. Bypass LDO to GND with at least a 1-μF ceramic capacitor. LDO is enabled when VBUS is above the VBUS UVLO threshold.                                                                                                                                                          |
| SGND     | B5             | 17    |     | Signal ground                                                                                                                                                                                                                                                                                                                                    |
| DGND     | A6             | 18    |     | Digital ground                                                                                                                                                                                                                                                                                                                                   |
| VZERO    | B6             | 19    | I   | This pin sets the zero-current output voltage level of the current shunt monitor.                                                                                                                                                                                                                                                                |
| VSHNT    | C5             | 21    | O   | Output of current shunt monitor. For positive currents (into battery) VSHNT > VZERO. For negative currents (out of the battery) VSHNT < VZERO.                                                                                                                                                                                                   |
| SWL      | F6             | 27    | I   | This is the switching node of the LED driver. Connect the inductor from the supply to the SWL pin. This pin is also used to sense the output voltage for open LED protection.                                                                                                                                                                    |
| CTRL     | D5             | 25    | I   | Control pin of the LED boost regulator. It is a multi-functional pin which can be used for enable control and PWM dimming.                                                                                                                                                                                                                       |
| COMP     | E6             | 26    | O   | Output of the transconductance error amplifier. Connect an external capacitor to this pin to compensate the regulator.                                                                                                                                                                                                                           |
| FB       | E5             | 29    | I   | Feedback pin for current. Connect the sense resistor from FB to GND.                                                                                                                                                                                                                                                                             |
| VSHRT    | A5             | 16    | I   | The voltage on this pin defines the battery voltage for transitioning from liner charge (pre-charge) to fast charge. A 10-μA current source is internally connected to this pin. Connect a resistor from this pin to ground to setup VSHORT reference. If the pin is left floating or tied to VDD an internal VSHORT reference of 2.1 V is used. |
| VIO      | E3             | 34    | I   | I/O reference voltage. A VIO level above 0.6 V disables automatic D+/D- detection.                                                                                                                                                                                                                                                               |
| INT      | D4             | 23    | O   | Interrupt pin (open drain). This pin is pulled low to signal to the main processor that a fault has occurred.                                                                                                                                                                                                                                    |
| OTG      | C4             | 13    | I   | Boost control pin. Boost mode is turned on whenever this pin is active. Polarity is user defined through I <sup>2</sup> C register. The pin is disabled by default and can be enabled through I <sup>2</sup> C register bit.                                                                                                                     |

## ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) <sup>(1)(2)</sup>

|                                                                  |                                                                                                         | VALUE      | UNIT |
|------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------|------------|------|
| Supply voltage range (with respect to PGND)                      | VBUS                                                                                                    | -2 to 20   | V    |
| Input/Output voltage range (with respect to PGND)                | SDA, SCL, DM, DP, SWL, VZERO, VSHRT, CSIN, CSOUT, CSOT, LDO, INT, OTG, VSYS, VSHNT, VDD, VIO, BAT, CTRL | -0.3 to 7  | V    |
|                                                                  | PMID, STAT                                                                                              | -0.3 to 20 |      |
|                                                                  | VDD                                                                                                     | 6.5        |      |
|                                                                  | SWC, BOOT                                                                                               | -0.7 to 20 |      |
|                                                                  | FB,COMP                                                                                                 | -0.3 to 3  |      |
|                                                                  | SWL                                                                                                     | -0.3 to 44 |      |
| Voltage difference between CSIN and CSOUT inputs (VCSIN -VCSOUT) |                                                                                                         | ± 7        | V    |
| Output current (average)                                         | SWC                                                                                                     | 1.5        | A    |
| Output current (continuous)                                      | LDO                                                                                                     | 100        | mA   |
| $\theta_{JA}$ Junction-to-ambient thermal resistance             | JEDEC 4 layer high-K board                                                                              | 100        | °C/W |
|                                                                  | 8 layer board, 1/3 Oz Cu, one solid ground plane                                                        | 60         |      |
| $T_A$ Operating ambient temperature range                        |                                                                                                         | -40 to 85  | °C   |
| $T_J$ Max operating junction temperature                         |                                                                                                         | 150        | °C   |
| $T_C$ Max operating case temperature                             |                                                                                                         | 150        | °C   |
| $T_{stg}$ Storage temperature                                    |                                                                                                         | -65 to 150 | °C   |
| ESD rating                                                       | (HBM) Human body model                                                                                  | ±2000      | V    |
|                                                                  | (CDM) Charged device model                                                                              | ±500       |      |

- (1) Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute–maximum–rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to network ground terminal.

## RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

|                     | MIN  | NOM | MAX | UNIT |
|---------------------|------|-----|-----|------|
| VBUS Supply voltage | 4    |     | 6   | V    |
| SWL Output voltage  | VBAT |     | 39  | V    |

## RECOMMENDED EXTERNAL COMPONENTS

over operating free-air temperature range (unless otherwise noted)

| PART NO.                         | VALUE      | SIZE            | MANUFACTURER |
|----------------------------------|------------|-----------------|--------------|
| <b>CHARGER INDUCTOR</b>          |            |                 |              |
| NR3012T1R0N                      | 1 $\mu$ H  | 3 x 3 x 1.2     | Taiyo Yuden  |
| CPL2512T1R0M                     | 1 $\mu$ H  | 2.5 x 1.5 x 1.2 | TDK          |
| MDT2520CN                        | 1 $\mu$ H  |                 | TOKO         |
| <b>WLED BOOST INDUCTOR</b>       |            |                 |              |
| ELL-VGG100M                      | 10 $\mu$ H | 3 x 3 x 1.5     | Panasonic    |
| VLF4010ST-100MR80                | 10 $\mu$ H | 4.3 x 4 x 1     | TDK          |
| 1098AS-100M                      | 10 $\mu$ H | 3 x 3.2 x 1.2   | TOKO         |
| <b>WLED BOOST SCHOTTKY DIODE</b> |            |                 |              |
| MBR0540                          |            | SOD-123         | ON-SEMI      |
| ZHCS400                          |            | SOD-323         | ZETEX        |

## ELECTRICAL CHARACTERISTICS

VBAT = 3.6 V ±5%, T<sub>J</sub> = 27°C (unless otherwise noted)

| PARAMETER                            |                                                                                                                             | TEST CONDITIONS                                                                                                                                | MIN                                                                 | TYP   | MAX  | UNIT |
|--------------------------------------|-----------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------|-------|------|------|
| INPUT CURRENTS                       |                                                                                                                             |                                                                                                                                                |                                                                     |       |      |      |
| I <sub>DISCHARGE</sub>               | Battery discharge current in high Impedance mode (CSIN, CSOUT,SWC, SWL, BAT, VSYS pins)                                     | 0°C < T <sub>J</sub> < 85°C, V <sub>BAT</sub> = 4.2 V                                                                                          | Charger HiZ mode<br>WLED disabled<br>Shunt monitor disabled         | 2     | 10   | μA   |
|                                      |                                                                                                                             |                                                                                                                                                | Charger HiZ mode<br>WLED enabled, no load<br>Shunt monitor disabled |       | 1800 |      |
|                                      |                                                                                                                             |                                                                                                                                                | Charger HiZ mode<br>WLED disabled<br>Shunt monitor enabled          |       | 60   |      |
| I <sub>VBUS</sub>                    | VBUS supply current                                                                                                         | V <sub>BUS</sub> > V <sub>BUS(min)</sub>                                                                                                       | Charger PWM ON                                                      | 10000 |      | μA   |
|                                      |                                                                                                                             |                                                                                                                                                | Charger PWM OFF                                                     |       | 5000 |      |
|                                      |                                                                                                                             | 0°C < T <sub>J</sub> < 85°C, HZ_MODE = 1                                                                                                       |                                                                     |       | 15   |      |
| I <sub>VBUS_LEAK</sub>               | Leakage current from battery to VBUS pin                                                                                    | 0°C < T <sub>J</sub> < 85°C, V <sub>BAT</sub> = 4.2 V HiZ mode                                                                                 |                                                                     |       | 5    | μA   |
| VOLTAGE REGULATION                   |                                                                                                                             |                                                                                                                                                |                                                                     |       |      |      |
| V <sub>OREG</sub>                    | Output charge voltage                                                                                                       | Operating in voltage regulation, programmable                                                                                                  | 3.5                                                                 |       | 4.44 | V    |
|                                      | Voltage regulation accuracy                                                                                                 | T <sub>A</sub> = 25°C                                                                                                                          | -0.5                                                                |       | 0.5  | %    |
|                                      |                                                                                                                             | Full temperature range                                                                                                                         | -1                                                                  |       | 1    |      |
| CURRENT REGULATION -FAST CHARGE      |                                                                                                                             |                                                                                                                                                |                                                                     |       |      |      |
| I <sub>CHARGE</sub>                  | Output charge current                                                                                                       | V <sub>SHRT</sub> ≤ V <sub>CSOUT</sub> < V <sub>OREG</sub> ,<br>V <sub>BUS</sub> > 5 V, R <sub>SNS</sub> = 20 mΩ,<br>LOW_CHG = 0, Programmable | 550                                                                 |       | 1250 | mA   |
|                                      |                                                                                                                             | V <sub>LOWV</sub> ≤ V <sub>CSOUT</sub> < V <sub>OREG</sub> ,<br>V <sub>BUS</sub> > 5 V, R <sub>SNS</sub> = 20 mΩ,<br>LOW_CHG = 1               |                                                                     | 150   | 200  |      |
| CHARGE TERMINATION DETECTION         |                                                                                                                             |                                                                                                                                                |                                                                     |       |      |      |
| I <sub>TERM</sub>                    | Termination charge current                                                                                                  | V <sub>CSOUT</sub> > V <sub>OREG</sub> -VRCH, V <sub>BUS</sub> > 5 V,<br>R <sub>SNS</sub> = 20 mΩ, Programmable                                | 50                                                                  |       | 400  | mA   |
|                                      | Deglitch time for charge termination                                                                                        | Both rising and falling, 2-mV overdrive,<br>t <sub>RISE</sub> , t <sub>FALL</sub> = 100 ns                                                     |                                                                     | 30    |      | ms   |
| CHARGE CURRENT ACCURACY              |                                                                                                                             |                                                                                                                                                |                                                                     |       |      |      |
| V <sub>OS, CHRGR</sub>               | Offset voltage, sense voltage amplifier<br>Charge current accuracy = V <sub>OS</sub> /(I <sub>SET</sub> ×R <sub>SNS</sub> ) | T <sub>A</sub> = 0°C to 85°C                                                                                                                   | -1                                                                  |       | 1    | mV   |
| BAD ADAPTOR DETECTION                |                                                                                                                             |                                                                                                                                                |                                                                     |       |      |      |
| V <sub>IN(MIN)</sub>                 | Input voltage lower limit                                                                                                   | Bad adaptor detection, V <sub>BUS</sub> falling                                                                                                | 3.6                                                                 | 3.8   | 4    | V    |
|                                      | Deglitch time for V <sub>BUS</sub> rising above V <sub>IN(MIN)</sub>                                                        | Rising voltage, 2-mV over drive,<br>t <sub>RISE</sub> = 100 ns                                                                                 |                                                                     | 30    |      | ms   |
|                                      | Hysteresis for V <sub>IN(MIN)</sub>                                                                                         | V <sub>BUS</sub> rising                                                                                                                        | 100                                                                 |       | 200  | mV   |
| I <sub>ADET</sub>                    | Current source to GND                                                                                                       | During bad adaptor detection                                                                                                                   | 20                                                                  | 30    | 40   | mA   |
| T <sub>INT</sub>                     | Detection interval                                                                                                          | Input power source detection                                                                                                                   |                                                                     | 2     |      | s    |
| INPUT BASED DYNAMIC POWER MANAGEMENT |                                                                                                                             |                                                                                                                                                |                                                                     |       |      |      |
| V <sub>IN_LOW</sub>                  | The threshold when input based DPM loop kicks in                                                                            | Charge mode, programmable                                                                                                                      | 4.2                                                                 |       | 4.76 | V    |
|                                      | DPM loop kick-in threshold tolerance                                                                                        |                                                                                                                                                | -2                                                                  |       | 2    | %    |

**ELECTRICAL CHARACTERISTICS (continued)**VBAT = 3.6 V ±5%, T<sub>j</sub> = 27°C (unless otherwise noted)

| PARAMETER                                             |                                                                                             | TEST CONDITIONS                                                                                                                         | MIN  | TYP  | MAX  | UNIT |
|-------------------------------------------------------|---------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------|------|------|------|------|
| INPUT CURRENT LIMITING                                |                                                                                             |                                                                                                                                         |      |      |      |      |
| I <sub>IN_LIMIT</sub>                                 | Input current limiting threshold                                                            | I <sub>IN_LIMIT</sub> = 100 mA                                                                                                          | 88   | 93   | 98   | mA   |
|                                                       |                                                                                             | I <sub>IN_LIMIT</sub> = 500 mA                                                                                                          | 450  | 475  | 500  |      |
|                                                       |                                                                                             | I <sub>IN_LIMIT</sub> = 975 mA                                                                                                          | 875  | 925  | 975  |      |
| VDD REGULATOR                                         |                                                                                             |                                                                                                                                         |      |      |      |      |
| V <sub>DD</sub>                                       | Internal bias regulator voltage                                                             | V <sub>BUS</sub> > V <sub>IN(min)</sub> or V <sub>SYS</sub> > V <sub>BATMIN</sub> ,<br>I <sub>VDD</sub> = 1 mA, C <sub>VDD</sub> = 1 μF | 2    |      | 6.5  | V    |
|                                                       | VDD output short current limit                                                              |                                                                                                                                         |      | 30   |      | mA   |
|                                                       | Voltage from BST pin to SWC pin                                                             | During charge or boost operation                                                                                                        |      |      | 6.5  | V    |
| BATTERY RECHARGE THRESHOLD                            |                                                                                             |                                                                                                                                         |      |      |      |      |
| V <sub>RCH</sub>                                      | Recharge threshold voltage                                                                  | Below V <sub>OREG</sub>                                                                                                                 | 100  | 130  | 160  | mV   |
|                                                       | Deglitch time                                                                               | V <sub>CSOUT</sub> decreasing below threshold,<br>t <sub>FALL</sub> = 100 ns, 10-mV overdrive                                           |      | 130  |      | ms   |
| STAT OUTPUT                                           |                                                                                             |                                                                                                                                         |      |      |      |      |
| V <sub>OL(STAT)</sub>                                 | Low-level output saturation voltage                                                         | I <sub>O</sub> = 10 mA, sink current                                                                                                    |      |      | 0.4  | V    |
|                                                       | High-level leakage current                                                                  | Voltage on STAT pin is 5 V                                                                                                              |      |      | 1    | μA   |
| REVERSE PROTECTION COMPARATOR                         |                                                                                             |                                                                                                                                         |      |      |      |      |
| V <sub>REV</sub>                                      | Reverse protection threshold,<br>V <sub>BUS-VCSOUT</sub>                                    | 2.3 V ≤ V <sub>CSOUT</sub> ≤ V <sub>OREG</sub> , V <sub>BUS</sub> falling                                                               | 0    | 40   | 100  | mV   |
| V <sub>REV-EXIT</sub>                                 | Reverse protection exit hysteresis                                                          | 2.3 V ≤ V <sub>CSOUT</sub> ≤ V <sub>OREG</sub>                                                                                          | 140  | 200  | 260  | mV   |
|                                                       | Deglitch time for V <sub>BUS</sub> rising above<br>V <sub>REV</sub> + V <sub>REV_EXIT</sub> | Rising voltage                                                                                                                          |      | 30   |      | ms   |
| VBUS UVLO                                             |                                                                                             |                                                                                                                                         |      |      |      |      |
| V <sub>UVLO</sub>                                     | IC active threshold voltage                                                                 | V <sub>BUS</sub> rising                                                                                                                 | 3.05 | 3.3  | 3.55 | V    |
| V <sub>UVLO_HYS</sub>                                 | IC active hysteresis                                                                        | V <sub>BUS</sub> falling from above V <sub>UVLO</sub>                                                                                   | 120  | 150  |      | mV   |
| PWM                                                   |                                                                                             |                                                                                                                                         |      |      |      |      |
| f <sub>PWM</sub>                                      | PWM frequency, charger                                                                      |                                                                                                                                         |      | 3    |      | MHz  |
| R <sub>DSON</sub>                                     | Internal top reverse blocking MOSFET on-resistance                                          | I <sub>IN_LIMIT</sub> = 500 mA,<br>Measured from VBUS to PMID                                                                           |      | 180  |      | mΩ   |
|                                                       | Internal top N-channel Switching MOSFET on-resistance                                       | Measured from PMID to SWC                                                                                                               |      | 120  |      |      |
|                                                       | Internal bottom N-channel MOSFET on-resistance                                              | Measured from SW to PGND                                                                                                                |      | 150  |      |      |
| D <sub>MAX</sub>                                      | Maximum duty cycle                                                                          |                                                                                                                                         |      | 99.5 |      | %    |
| D <sub>MIN</sub>                                      | Minimum duty cycle                                                                          |                                                                                                                                         | 0    |      |      | %    |
|                                                       | Synchronous mode to nonsynchronous mode transition current threshold <sup>(1)</sup>         | Low-side MOSFET cycle-by-cycle current sensing                                                                                          |      | 100  |      | mA   |
| BOOST MODE OPERATION FOR VBUS (OPA_MODE=1, HZ_MODE=0) |                                                                                             |                                                                                                                                         |      |      |      |      |
| V <sub>BUS_B</sub>                                    | Boost output voltage (to pin VBUS)                                                          | 2.5 V < V <sub>BUS</sub> < 4.5 V; Including line and load regulation over full temp range                                               | 4.75 | 5    | 5.25 | V    |
| I <sub>BO</sub>                                       | Maximum output current for boost                                                            | V <sub>BUS_B</sub> = 5 V, 2.5 V < V <sub>BUS</sub> < 4.5 V                                                                              | 200  |      |      | mA   |
| I <sub>BLIMIT</sub>                                   | Cycle by cycle current limit for boost                                                      | V <sub>BUS_B</sub> = 5 V, 2.5 V < V <sub>SYS</sub> < 4.5 V                                                                              |      | 1    |      | A    |
| V <sub>BUSOVP</sub>                                   | Over voltage protection threshold for boost (VBUS pin)                                      | Threshold over V <sub>BUS</sub> to turn off converter during boost                                                                      | 5.8  | 6    | 6.2  | V    |
|                                                       | VBUSOVP hysteresis                                                                          | V <sub>BUS</sub> falling from above V <sub>BUSOVP</sub>                                                                                 |      | 200  |      | mV   |
| V <sub>BATMAX</sub>                                   | Maximum battery voltage for boost                                                           | V <sub>SYS</sub> rising edge during boost                                                                                               | 4.75 | 4.9  | 5.05 | V    |
|                                                       | VBATMAX hysteresis                                                                          | V <sub>SYS</sub> falling from above V <sub>BATMAX</sub>                                                                                 |      | 200  |      | mV   |

(1) Bottom N-channel MOSFET always turns on for ~60 ns and then turns off if current is too low.

## ELECTRICAL CHARACTERISTICS (continued)

VBAT = 3.6 V ±5%, T<sub>J</sub> = 27°C (unless otherwise noted)

| PARAMETER                               |                                                                    | TEST CONDITIONS                                                                                              | MIN  | TYP | MAX                    | UNIT |
|-----------------------------------------|--------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------|------|-----|------------------------|------|
| V <sub>BATMIN</sub>                     | Minimum battery voltage for boost (VSYS pin)                       | During boosting                                                                                              |      | 2.5 |                        | V    |
|                                         |                                                                    | Before boost starts                                                                                          |      | 2.9 | 3.05                   |      |
|                                         | Boost output resistance at high impedance mode (From VBUS to PGND) | HZ_MODE = 1                                                                                                  | 500  |     |                        | kΩ   |
| <b>CHARGER PROTECTION</b>               |                                                                    |                                                                                                              |      |     |                        |      |
| V <sub>OVP-IN_USB</sub>                 | Input V <sub>BUSOVP</sub> threshold voltage                        | Threshold over V <sub>BUS</sub> to turn off converter during charge                                          | 6.3  | 6.5 | 6.7                    | V    |
|                                         | V <sub>OVP_IN_USB</sub> hysteresis                                 | V <sub>BUS</sub> falling from above V <sub>OVP_IN</sub>                                                      |      | 140 |                        | mV   |
| V <sub>OVP</sub>                        | Battery OVP threshold voltage                                      | V <sub>CSOUT</sub> threshold over V <sub>OREG</sub> to turn off charger during charge (% V <sub>OREG</sub> ) | 110  | 117 | 121                    | %    |
|                                         | V <sub>OVP</sub> hysteresis                                        | Lower limit for V <sub>CSOUT</sub> falling from > V <sub>OVP</sub> (% V <sub>OREG</sub> )                    |      | 11  |                        | %    |
| I <sub>LIMIT</sub>                      | Cycle-by-cycle current limit for charge                            | Charge mode operation                                                                                        | 1.8  | 2.4 | 3                      | A    |
| V <sub>SHORT</sub>                      | Trickle to fast charge threshold                                   | V <sub>CSOUT</sub> rising, VSHRT connected to VDD                                                            | 2    | 2.1 | 2.2                    | V    |
|                                         |                                                                    | Resistor connected from VSHRT to GND                                                                         | 1.8  |     | V <sub>BUS</sub> – 0.7 | V    |
|                                         | Internal current source connected to VSHRT pin                     |                                                                                                              | 9.4  | 10  | 10.6                   | μA   |
|                                         | V <sub>SHORT</sub> hysteresis                                      | V <sub>CSOUT</sub> falling from above VSHORT                                                                 |      | 100 |                        | mV   |
|                                         | Enable threshold for internal V <sub>SHORT</sub> reference         | percentage of VDD                                                                                            |      | 90  |                        | %    |
| I <sub>SHORT</sub>                      | Trickle charge charging current                                    | V <sub>CSOUT</sub> ≤ V <sub>SHORT</sub>                                                                      | 20   | 30  | 40                     | mA   |
| T <sub>CF</sub>                         | Thermal regulation threshold                                       | Charge current begins to taper down                                                                          |      | 120 |                        | °C   |
| T <sub>32S</sub>                        | Time constant for the 32-second timer                              | 32 second mode                                                                                               |      | 32  |                        | s    |
| <b>WLED VOLTAGE AND CURRENT CONTROL</b> |                                                                    |                                                                                                              |      |     |                        |      |
| V <sub>REF</sub>                        | Voltage feedback regulation voltage                                |                                                                                                              | 198  | 203 | 208                    | mV   |
| V <sub>REF_PWM</sub>                    | Voltage feedback regulation voltage under brightness control       | V <sub>FB</sub> [4:0] = 01110 (V <sub>FB</sub> = 25%)                                                        | 47   | 50  | 53                     | mV   |
|                                         |                                                                    | V <sub>FB</sub> [4:0] = 01110 (V <sub>FB</sub> = 10%)                                                        | 17   | 20  | 23                     |      |
| f <sub>CTRL</sub>                       | PWM dimming frequency                                              |                                                                                                              | 1    |     | 100                    | kHz  |
| t <sub>CNTRL, MIN</sub>                 | Minimum on-time for PWM dimming pulse                              |                                                                                                              | 2.2  |     |                        | μs   |
| I <sub>FB</sub>                         | Voltage feedback input bias current                                | V <sub>FB</sub> = 200 mV                                                                                     |      |     | 1                      | μA   |
| f <sub>PWM</sub>                        | PWM frequency, WLED boost                                          |                                                                                                              |      | 600 |                        | kHz  |
| D <sub>max</sub>                        | Maximum duty cycle                                                 | V <sub>FB</sub> = 100 mV                                                                                     | 90   | 93  |                        | %    |
| t <sub>min_on</sub>                     | Minimum ON pulse width                                             |                                                                                                              |      | 40  |                        | ns   |
| L                                       | Inductor                                                           |                                                                                                              | 10   |     | 22                     | μH   |
| C <sub>OUT</sub>                        | Output capacitor                                                   |                                                                                                              | 0.47 |     | 10                     | μF   |
| <b>WLED POWER SWITCH</b>                |                                                                    |                                                                                                              |      |     |                        |      |
| R <sub>DS(on)</sub>                     | N-channel MOSFET on-resistance                                     | V <sub>SYS</sub> = 3.6 V                                                                                     |      | 300 | 600                    | mΩ   |
| I <sub>LN_NFET</sub>                    | N-channel leakage current                                          | V <sub>SWL</sub> = 30 V, T <sub>A</sub> = 25°C                                                               |      |     | 1                      | μA   |

**ELECTRICAL CHARACTERISTICS (continued)**VBAT = 3.6 V ±5%, T<sub>j</sub> = 27°C (unless otherwise noted)

| PARAMETER                    |                                                          | TEST CONDITIONS                                                                 | MIN  | TYP | MAX | UNIT |
|------------------------------|----------------------------------------------------------|---------------------------------------------------------------------------------|------|-----|-----|------|
| <b>WLED PROTECTION</b>       |                                                          |                                                                                 |      |     |     |      |
| V <sub>UVLO</sub>            | Under Voltage Lock Out (V <sub>SYST</sub> pin)           | V <sub>SYST</sub> falling                                                       |      | 2.2 | 2.5 | V    |
|                              | UVLO hysteresis                                          |                                                                                 |      | 70  |     | mV   |
| V <sub>OVP</sub>             | Over Voltage Protection threshold                        |                                                                                 | 35   | 37  | 39  | V    |
| I <sub>LIM</sub>             | N-Channel MOSFET current limit                           | D = D <sub>max</sub>                                                            | 560  | 700 | 840 | mA   |
| I <sub>LIM_Start</sub>       | Startup current limit                                    | D = D <sub>max</sub>                                                            |      | 400 |     | mA   |
| t <sub>HALF_LIM</sub>        | Time step for half current limit                         |                                                                                 |      | 5   |     | ms   |
| t <sub>REF</sub>             | V <sub>REF</sub> filter time constant                    |                                                                                 |      | 180 |     | μs   |
| t <sub>step</sub>            | V <sub>REF</sub> ramp up time                            |                                                                                 |      | 213 |     | μs   |
| <b>CURRENT SHUNT MONITOR</b> |                                                          |                                                                                 |      |     |     |      |
| V <sub>CM</sub>              | Common-mode input range                                  | V <sub>CSIN</sub> = V <sub>CSOUT</sub>                                          | -0.3 |     | 7   | V    |
| CMR                          | Common-mode rejection                                    | V <sub>CSIN</sub> = 2.7 V to 5 V, V <sub>CSIN</sub> - V <sub>CSOUT</sub> = 0 mV | 100  |     |     | dB   |
| V <sub>OS, CSM</sub>         | Offset-voltage, referred to input                        | T <sub>A</sub> = 0°C to 60°C                                                    | -75  |     | 75  | μV   |
|                              |                                                          | T <sub>A</sub> = -20°C to 85°C                                                  | -85  |     | 85  |      |
| G                            | Gain                                                     |                                                                                 |      | 25  |     | V/V  |
|                              | Gain error                                               |                                                                                 | -1   |     | 1   | %    |
| V <sub>SHNT</sub>            | Swing to positive power supply rail (V <sub>SYST</sub> ) | V <sub>SYST</sub> - V <sub>SHNT</sub>                                           | 100  |     |     | mV   |
|                              | Swing to GND                                             | V <sub>SHNT</sub> - V <sub>GND</sub>                                            | 100  |     |     |      |
| GBW                          | Bandwidth                                                | C <sub>LOAD</sub> = 10 pF                                                       |      | 9   |     | kHz  |
| I <sub>VZERO</sub>           | VZERO bias current                                       | T <sub>A</sub> = -20°C to 85°C                                                  |      |     | 10  | nA   |
| V <sub>ZERO</sub>            | Swing to positive power supply rail (V <sub>SYST</sub> ) | V <sub>SYST</sub> - V <sub>ZERO</sub>                                           | 1.5  |     |     | V    |
|                              | Swing to GND                                             | V <sub>ZERO</sub> - V <sub>GND</sub>                                            | 0.7  |     |     |      |
| V <sub>UVLO</sub>            | Under voltage lock out (V <sub>SYST</sub> pin)           | V <sub>SYST</sub> falling                                                       |      | 2.2 | 2.5 | V    |
|                              | UVLO hysteresis                                          |                                                                                 |      | 70  |     | mV   |
| <b>LDO</b>                   |                                                          |                                                                                 |      |     |     |      |
| V <sub>LDO</sub>             | LDO Output Voltage                                       | V <sub>IN</sub> = 5.5V                                                          | 4.8  | 4.9 | 5   | V    |
|                              | PSRR                                                     | f = 100 Hz, CLDO = 1.0 μF                                                       |      | 60  |     | dB   |
| I <sub>LDO</sub>             | Maximum LDO Output Current                               |                                                                                 | 60   |     |     | mA   |
| V <sub>DO</sub>              | Dropout Voltage                                          | V <sub>IN</sub> = 4.5 V, ILDO = 50 mA                                           |      | 100 | 250 | mV   |
| <b>D+/D- DETECTION</b>       |                                                          |                                                                                 |      |     |     |      |
| V <sub>DP_SCR</sub>          | D+ voltage source                                        |                                                                                 | 0.5  | 0.6 | 0.7 | V    |
|                              | D+ voltage source output current                         |                                                                                 | 250  |     |     | μA   |
| I <sub>DM_SINK</sub>         | D- current sink                                          |                                                                                 | 50   | 100 | 150 | μA   |
| C <sub>I</sub>               | Input capacitance                                        | DM pin, switch open                                                             |      | 4.5 | 5   | pF   |
|                              |                                                          | DP pin, switch open                                                             |      | 4.5 | 5   |      |
| I <sub>I</sub>               | Input leakage                                            | DM pin, switch open                                                             | -1   |     | 1   | μA   |
|                              |                                                          | DP pin, switch open                                                             | -1   |     | 1   |      |
| V <sub>DP_LOW</sub>          | DP low comparator threshold                              |                                                                                 | 0.8  |     |     | V    |
| V <sub>DM_HIGH</sub>         | DM high comparator threshold                             |                                                                                 | 0.8  |     |     | V    |
| V <sub>DM_LOW</sub>          | DM low comparator threshold                              |                                                                                 |      |     | 475 | mV   |

**ELECTRICAL CHARACTERISTICS (continued)**

VBAT = 3.6 V ±5%, T<sub>J</sub> = 27°C (unless otherwise noted)

| PARAMETER                                                            |                                    | TEST CONDITIONS                                | MIN | TYP      | MAX  | UNIT |
|----------------------------------------------------------------------|------------------------------------|------------------------------------------------|-----|----------|------|------|
| <b>LOGIC LEVELS AND TIMING CHARACTERISTICS (SCL, SDA, CTRL, INT)</b> |                                    |                                                |     |          |      |      |
| V <sub>OL</sub>                                                      | Output low threshold level         | I <sub>O</sub> = 3 mA, sink current (SDA, INT) |     |          | 0.4  | V    |
|                                                                      | Input low threshold level          |                                                |     |          | 0.4  |      |
|                                                                      | Input high threshold level         |                                                | 1.2 |          |      |      |
| I <sub>(bias)</sub>                                                  | Input bias current (SCL, SDA, INT) | V <sub>IO</sub> = 1.8 V                        |     |          | 1    | μA   |
| f <sub>SCL</sub>                                                     | SCL clock frequency                |                                                |     |          | 400  | kHz  |
| R <sub>CTRL</sub>                                                    | CTRL pull down resistor            |                                                | 400 | 800      | 1600 | kΩ   |
| t <sub>OFF</sub>                                                     | CTRL pulse width to shutdown       | CTRL high to low                               | 2.5 |          |      | ms   |
|                                                                      | 7-bit slave address                |                                                |     | 1101 010 |      |      |
| <b>OSCILLATOR</b>                                                    |                                    |                                                |     |          |      |      |
| f <sub>OSC</sub>                                                     | Oscillator frequency               |                                                |     | 3        |      | MHz  |
|                                                                      | Frequency accuracy                 | T <sub>A</sub> = -40°C to 85°C                 | -10 |          | 10   | %    |
| <b>THERMAL SHUTDOWN</b>                                              |                                    |                                                |     |          |      |      |
| T <sub>SHTDWN</sub>                                                  | Thermal trip point                 |                                                |     | 165      |      | °C   |
|                                                                      | Thermal hysteresis                 |                                                |     | 10       |      |      |

## TYPICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$ , unless otherwise specified.

### Switching Charger

#### I<sup>2</sup>C CONTROLLED START UP

$V_{\text{BUS}} = 5.5\text{ V}$ ,  $V_{\text{BAT}} = 3.3\text{ V}$ ,  
 $I_{\text{IN\_limit}} = 975\text{ mA}$ ,  $I_{\text{CHARGE}} = 950\text{ mA}$

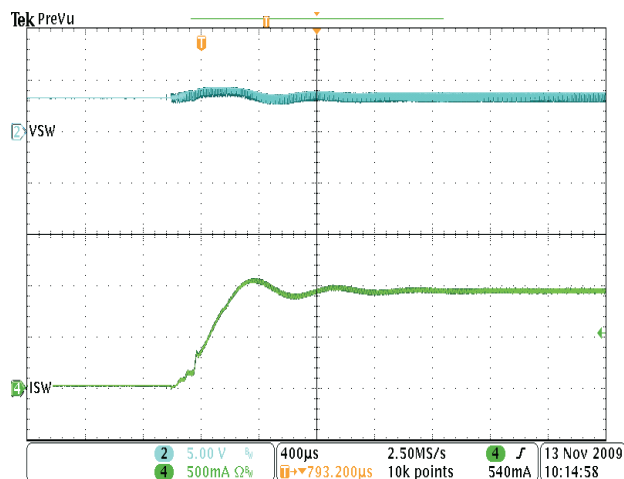


Figure 1.

#### I<sup>2</sup>C CONTROLLED START UP

$V_{\text{BUS}} = 5.5\text{ V}$ ,  $V_{\text{BAT}} = 3.3\text{ V}$ ,  
 $I_{\text{IN\_limit}} = 975\text{ mA}$ ,  $I_{\text{CHARGE}} = 950\text{ mA}$

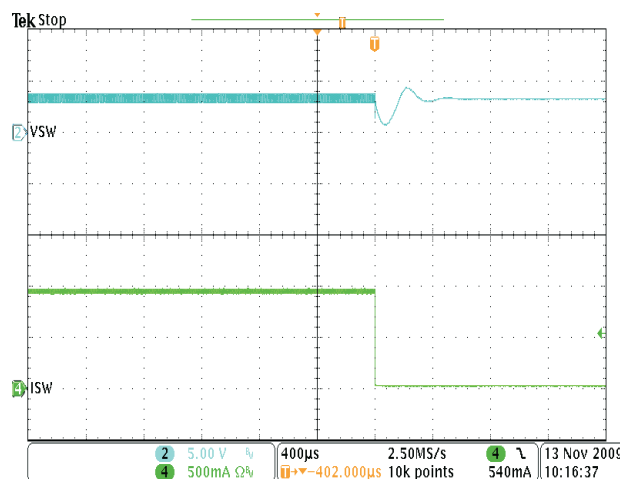


Figure 2.

#### PWM CHARGE OPERATION

$V_{\text{BUS}} = 5\text{ V}$ ,  $I_{\text{CHARGE}} = 150\text{ mA}$

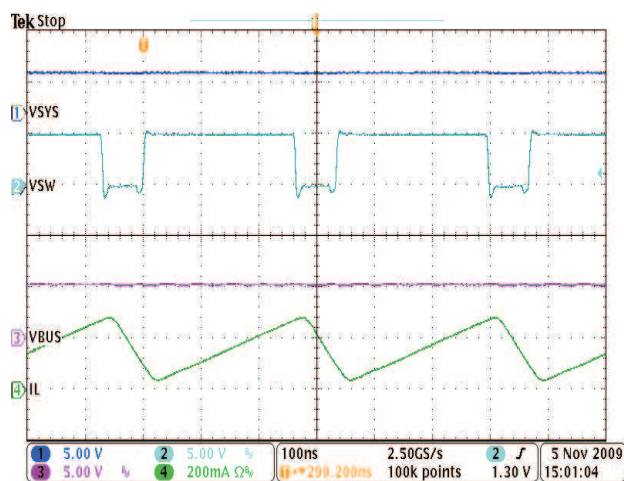


Figure 3.

#### PWM CHARGE OPERATION

$V_{\text{BUS}} = 5\text{ V}$ ,  $I_{\text{CHARGE}} = 150\text{ mA}$

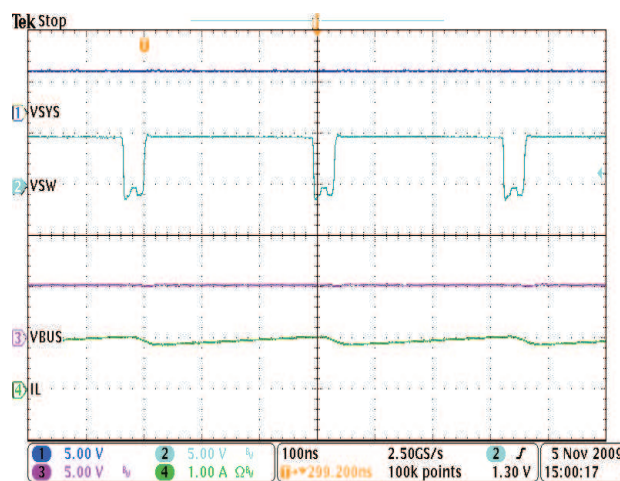


Figure 4.

## TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$ , unless otherwise specified.

**TRANSIENT RESPONSE**  
0-A - 1-A Transient on  $V_{SYS}$ ,  $V_{BUS} = 5.5\text{ V}$ ,  
 $V_{BAT} = 3.2\text{ V}$ ,  $V_{OREG} = 4\text{ V}$ ,  
 $I_{CHARGE} = 950\text{ mA}$ ,  $I_{IN\_limit} = 975\text{ mA}$

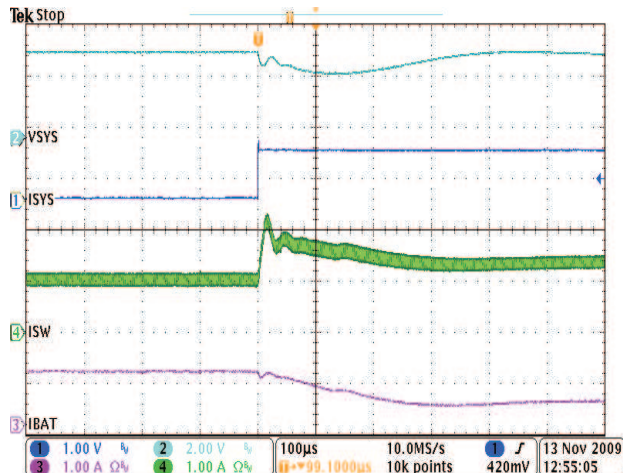


Figure 5.

**TRANSIENT RESPONSE**  
0-A - 1-A Transient on  $V_{SYS}$ ,  $V_{BUS} = 5.5\text{ V}$ ,  
 $V_{BAT} = 3.2\text{ V}$ ,  $V_{OREG} = 4\text{ V}$ ,  
 $I_{CHARGE} = 950\text{ mA}$ ,  $I_{IN\_limit} = 975\text{ mA}$

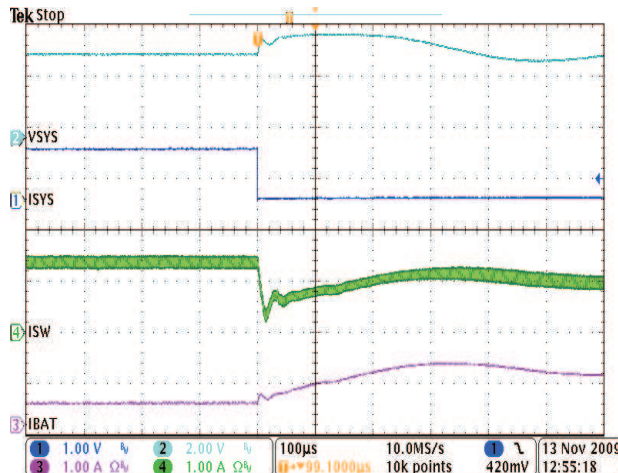


Figure 6.

**TRANSIENT RESPONSE**  
0-A - 1-A Transient on  $V_{SYS}$ ,  $V_{BUS} = 5.5\text{ V}$ ,  
 $V_{BAT} = 4\text{ V}$ ,  $V_{OREG} = 4\text{ V}$ ,  
 $I_{CHARGE} = 950\text{ mA}$ ,  $I_{IN\_limit} = 975\text{ mA}$

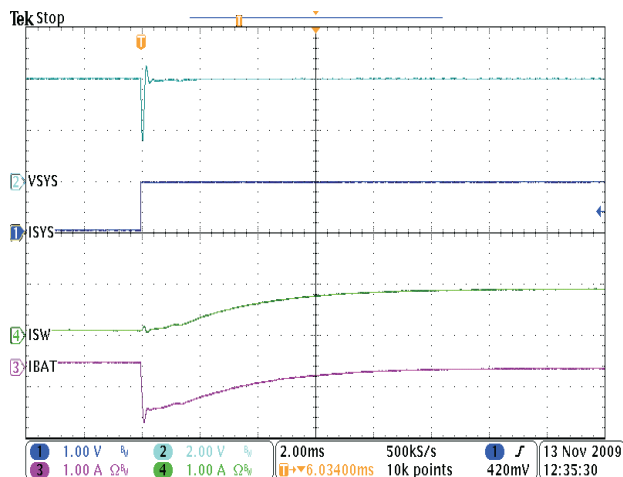


Figure 7.

**TRANSIENT RESPONSE**  
0-A - 1-A Transient on  $V_{SYS}$ ,  $V_{BUS} = 5.5\text{ V}$ ,  
 $V_{BAT} = 4\text{ V}$ ,  $V_{OREG} = 4\text{ V}$ ,  
 $I_{CHARGE} = 950\text{ mA}$ ,  $I_{IN\_limit} = 975\text{ mA}$

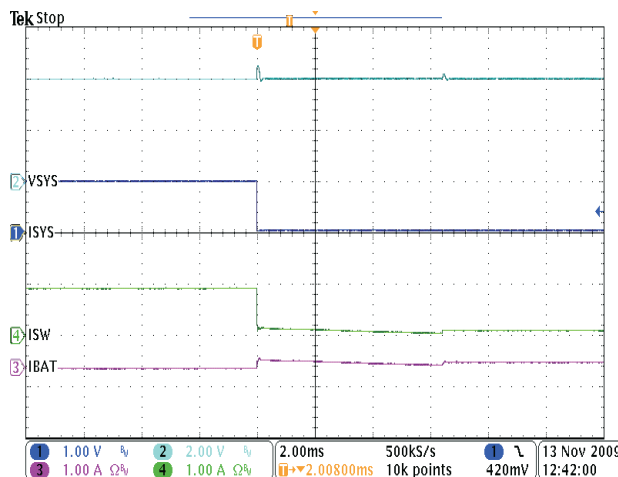


Figure 8.

## TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$ , unless otherwise specified.

**TRANSIENT RESPONSE**  
 0-A - 1-A Transient on  $V_{SYS}$ ,  $V_{BUS} = 5.5\text{ V}$ ,  
 No Battery,  $V_{OREG} = 4\text{ V}$ ,  
 $I_{CHARGE} = 950\text{ mA}$ ,  $I_{IN\_limit} = 975\text{ mA}$

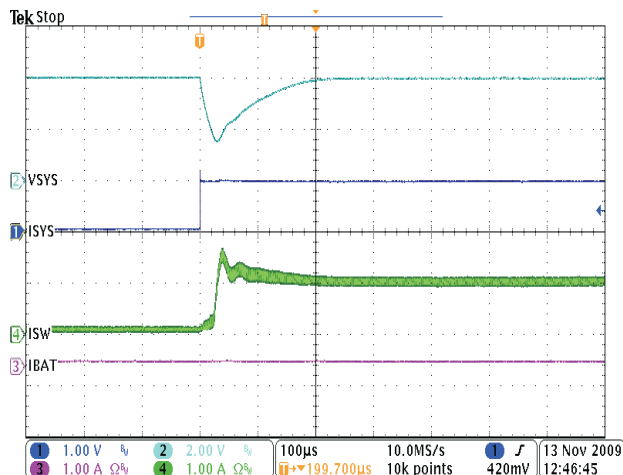


Figure 9.

**TRANSIENT RESPONSE**  
 0-A - 1-A Transient on  $V_{SYS}$ ,  $V_{BUS} = 5.5\text{ V}$ ,  
 No Battery,  $V_{OREG} = 4\text{ V}$ ,  
 $I_{CHARGE} = 950\text{ mA}$ ,  $I_{IN\_limit} = 975\text{ mA}$

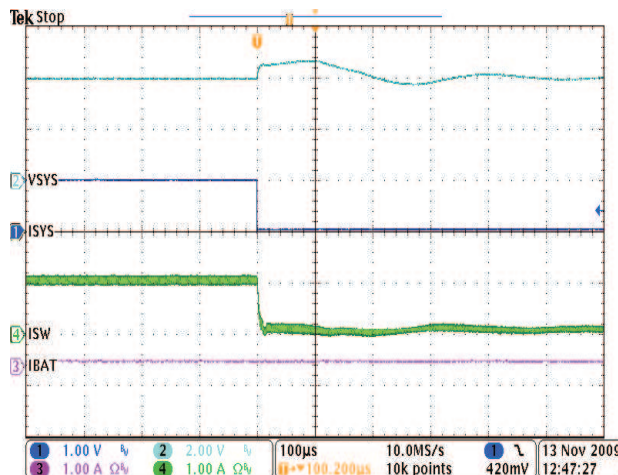


Figure 10.

**BAD ADAPTOR DETECTION**  
 $V_{BUS} = 5.5\text{ V}$ ,  $R_{IN} = 60\ \Omega$ ,  
 $V_{BAT} = 3\text{ V}$  (#165)

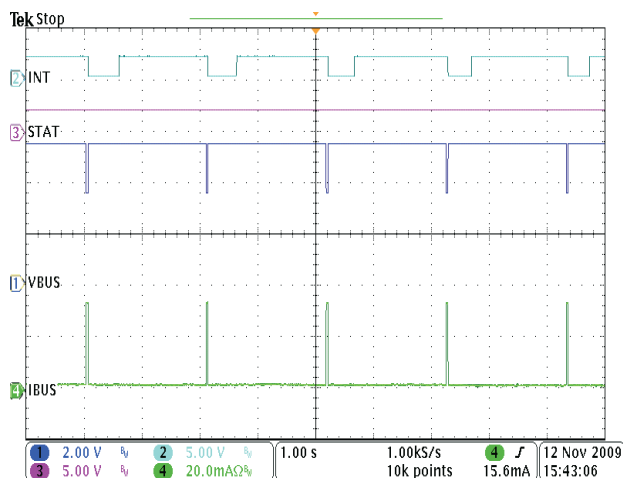


Figure 11.

**CHARGING CURVE**  
 1500 mAh Li-ion, 5.55 Whr,  
 $I_{CHARGE} = 950\text{ mA}$ ,  $I_{IN\_limit} = 975\text{ mA}$

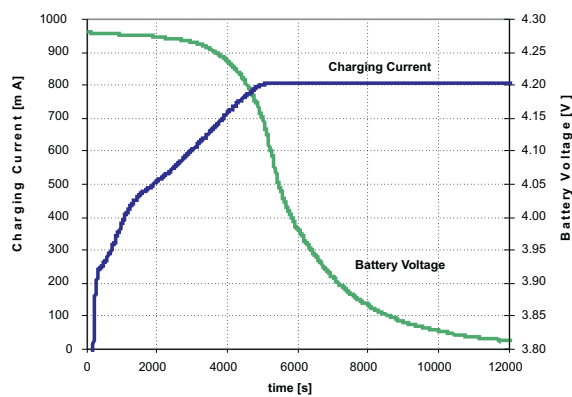


Figure 12.

## TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$ , unless otherwise specified.

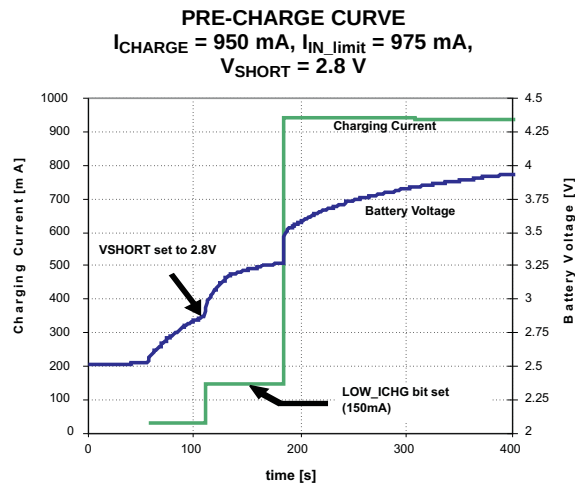


Figure 13.

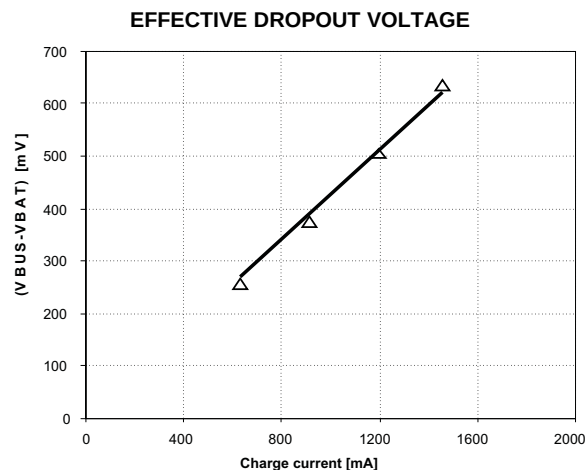


Figure 14.

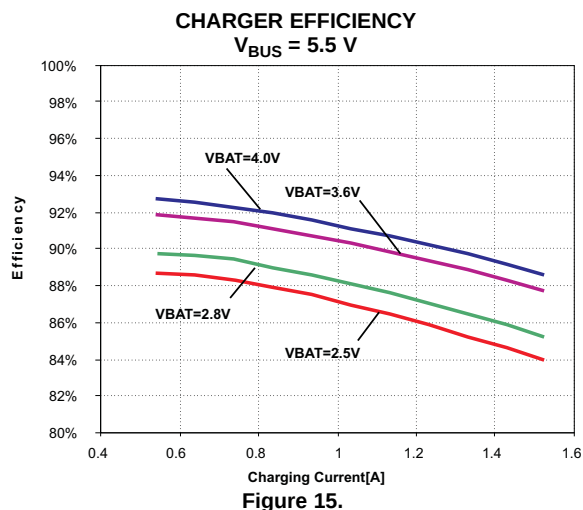


Figure 15.

## TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$ , unless otherwise specified.

### OTG Boost

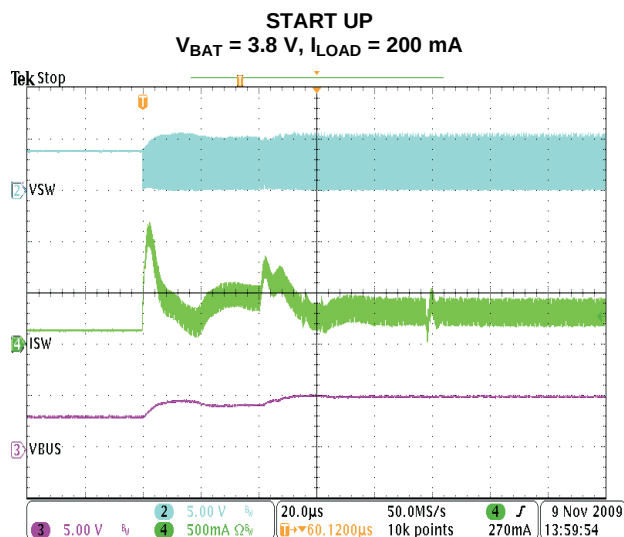


Figure 16.

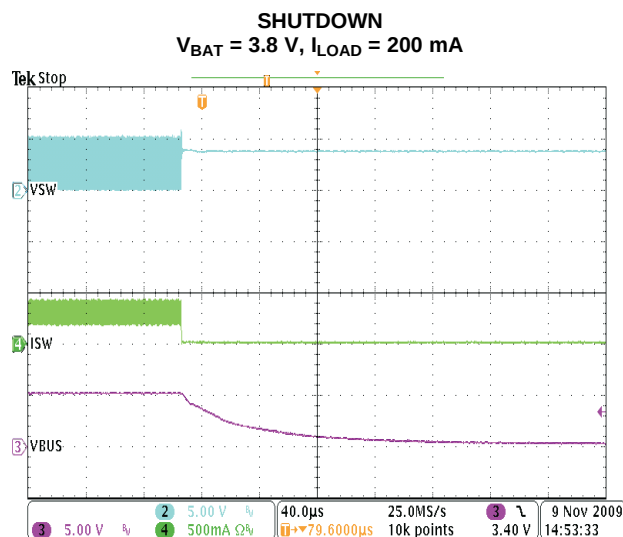


Figure 17.

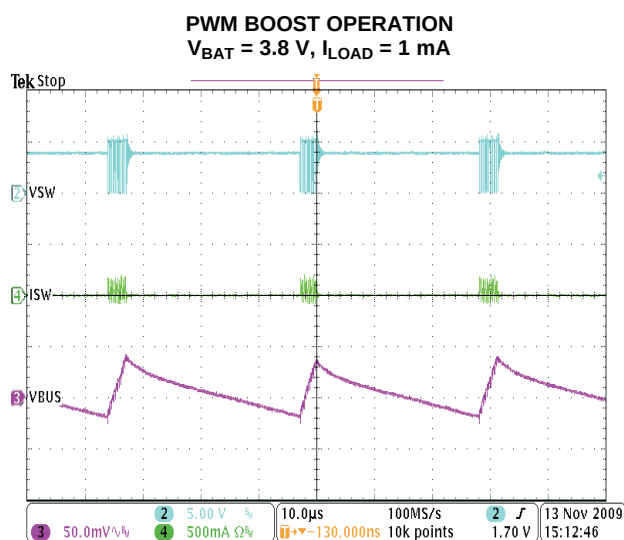


Figure 18.

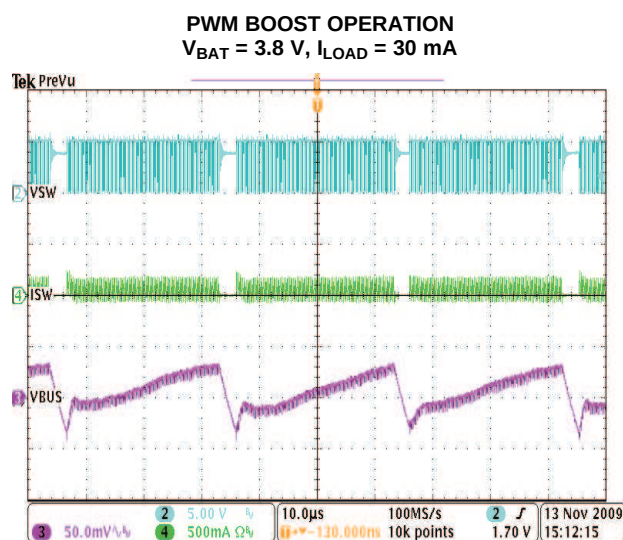


Figure 19.

## TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$ , unless otherwise specified.

**PWM BOOST OPERATION**  
 $V_{BAT} = 3.8\text{ V}$ ,  $I_{LOAD} = 200\text{ mA}$

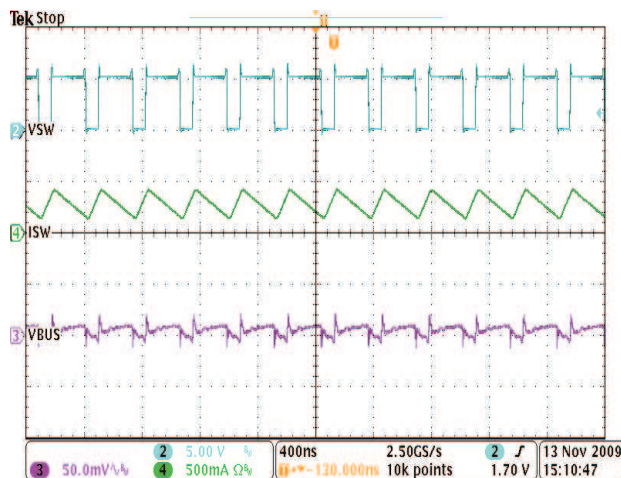


Figure 20.

**TRANSIENT RESPONSE**  
 $V_{BAT} = 3.8\text{ V}$ ,  $I_{LOAD} = 5\text{ mA} - 200\text{ mA}$

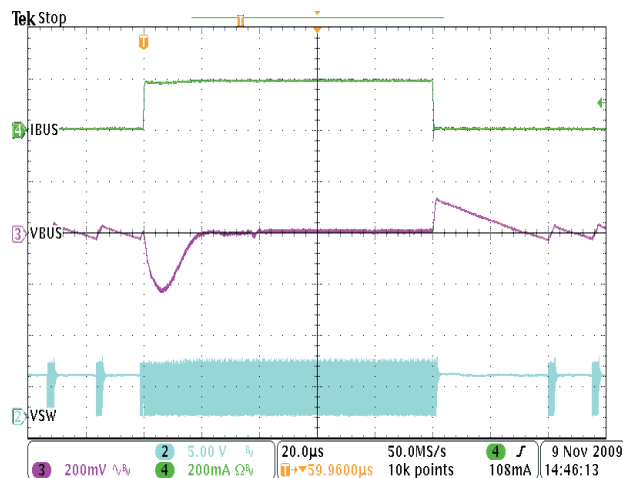


Figure 21.

**I<sup>2</sup>C CONTROLLED VOLTAGE STEP**  
 $V_{BAT} = 3.8\text{ V}$ ,  $I_{LOAD} = 200\text{ mA}$

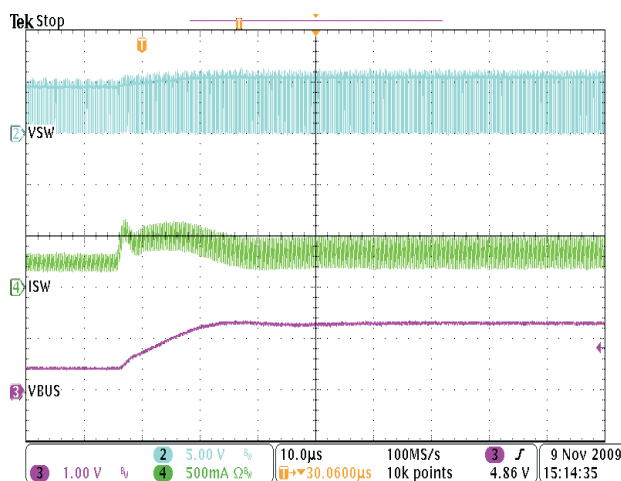


Figure 22.

**I<sup>2</sup>C CONTROLLED VOLTAGE STEP**  
 $V_{BAT} = 3.8\text{ V}$ ,  $I_{LOAD} = 200\text{ mA}$

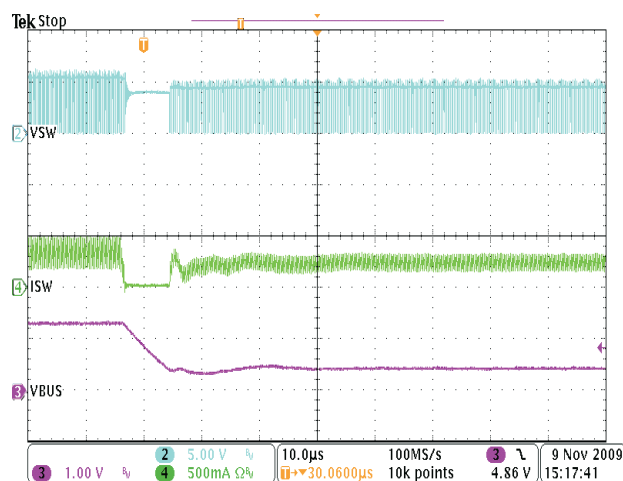


Figure 23.

## TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$ , unless otherwise specified.

### LDO

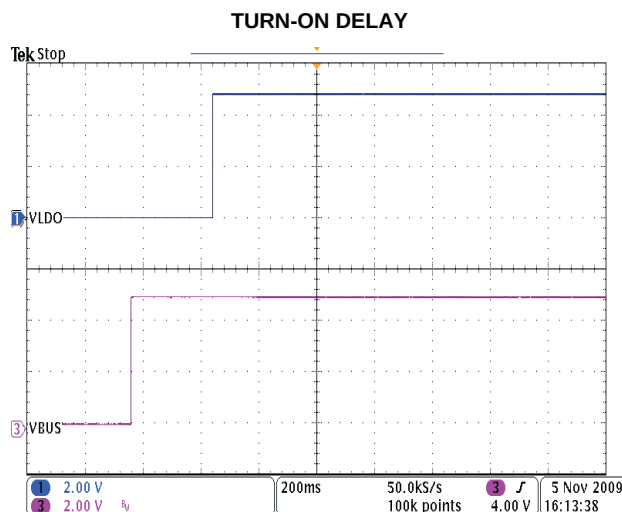


Figure 24.

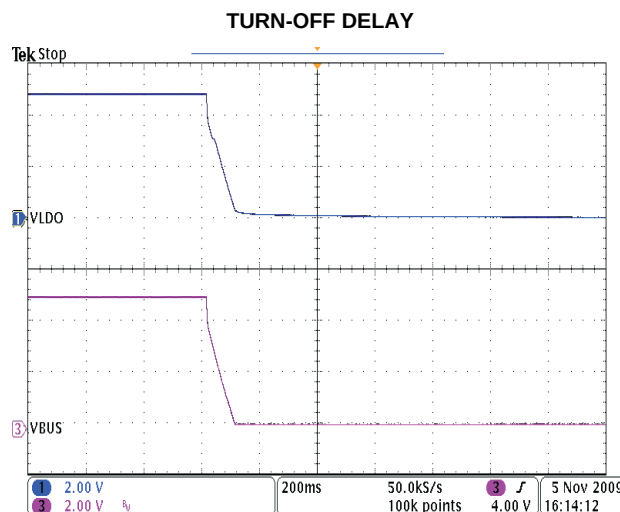


Figure 25.

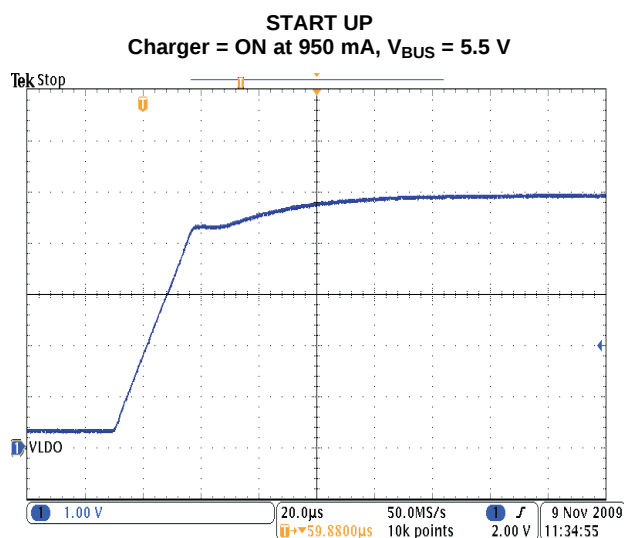


Figure 26.

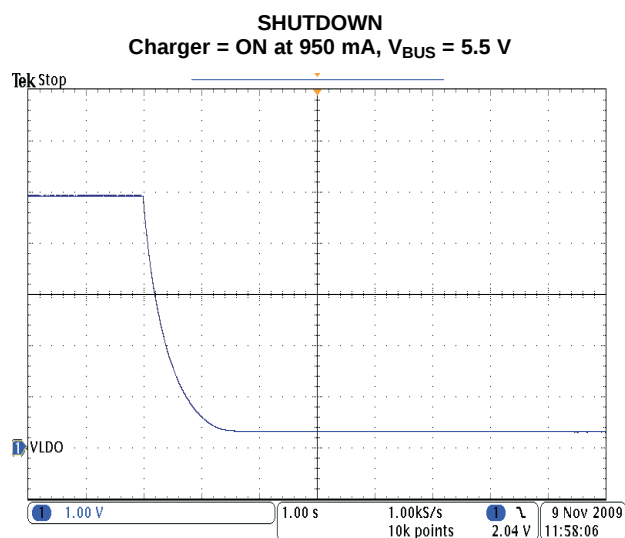


Figure 27.

## TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$ , unless otherwise specified.

**START UP**  
50 mA Load, Charger = ON at 950 mA,  
 $V_{BUS} = 5.5\text{ V}$

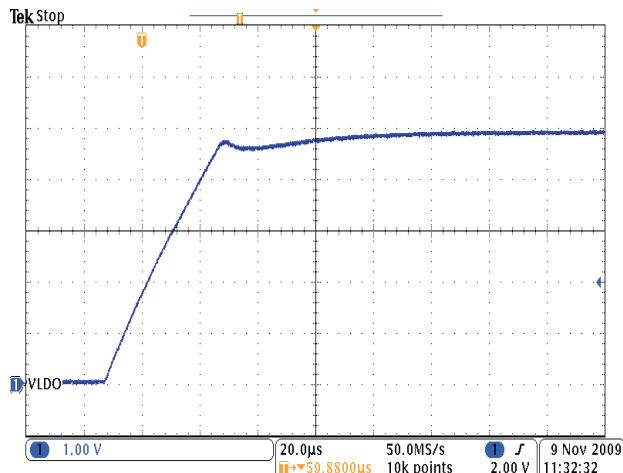


Figure 28.

**SHUTDOWN**  
50 mA Load, Charger = ON at 950 mA,  
 $V_{BUS} = 5.5\text{ V}$

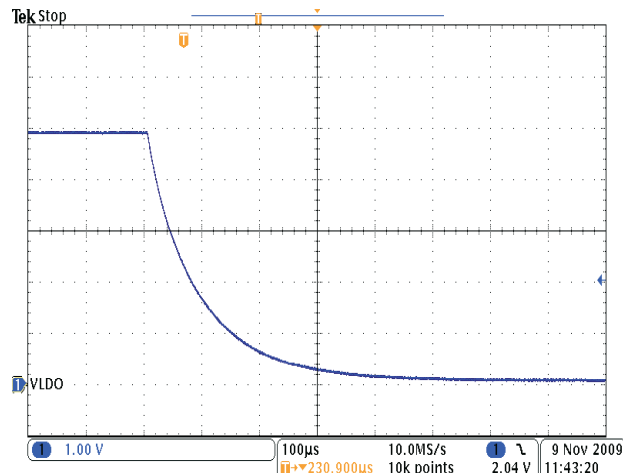


Figure 29.

**TRANSIENT RESPONSE**  
Charger OFF,  $I_{LOAD} = 5\text{ mA}$  to  $50\text{ mA}$ ,  
 $V_{BUS} = 5.5\text{ V}$

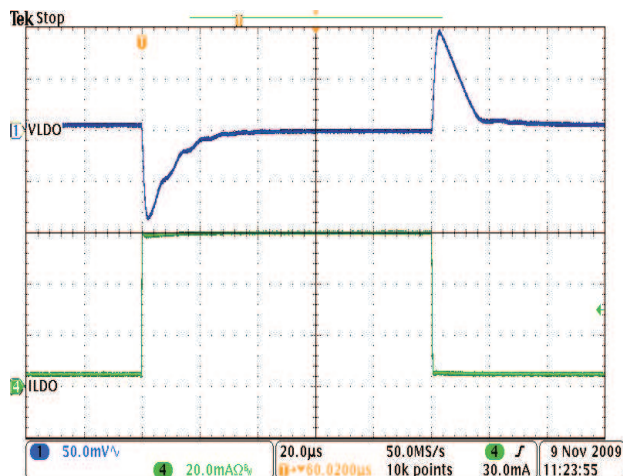


Figure 30.

**OTG BOOST EFFICIENCY**  
 $V_{BUS} = 5.5\text{ V}$

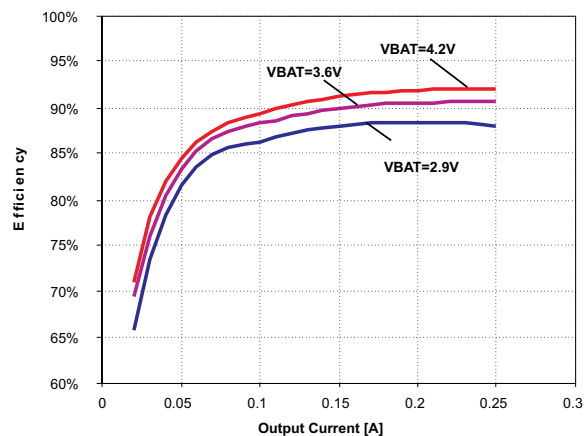


Figure 31.

## TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$ , unless otherwise specified.

### WLED Boost

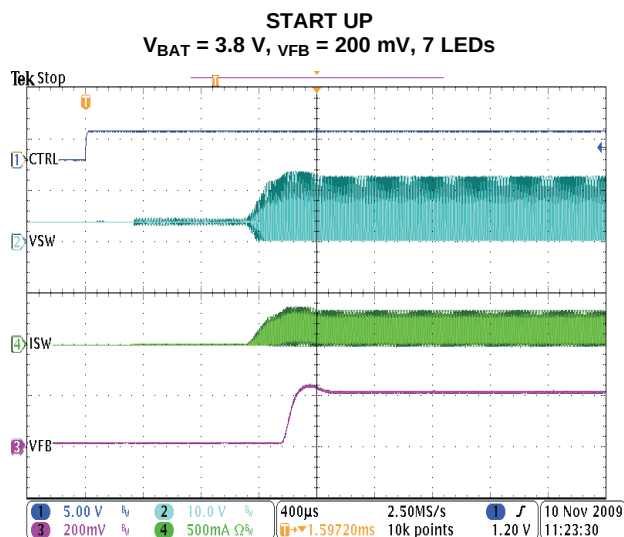


Figure 32.

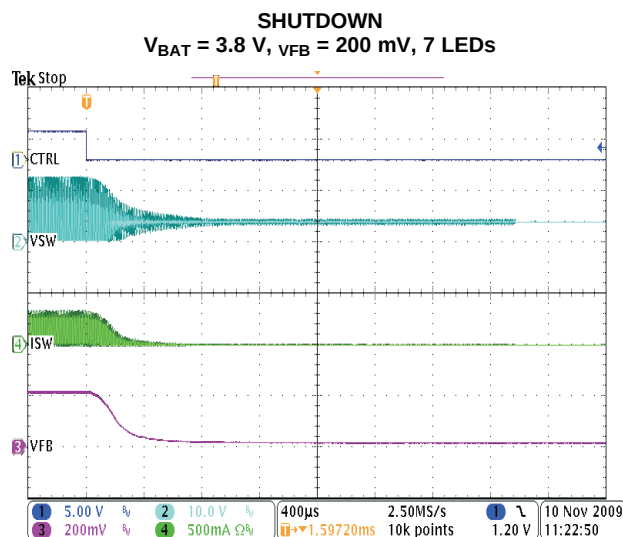


Figure 33.

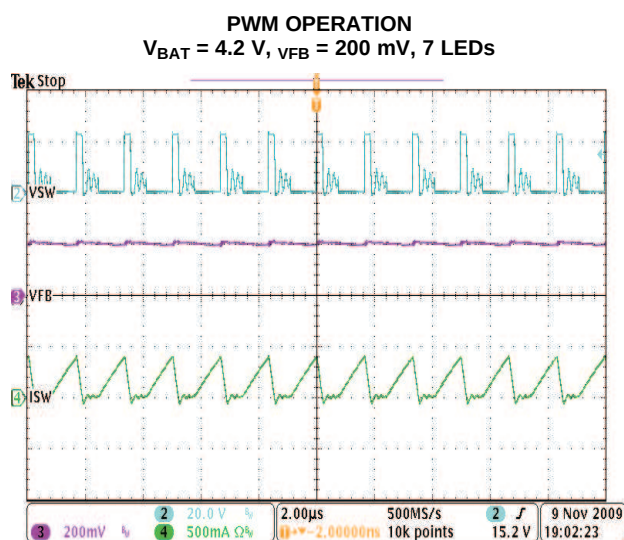


Figure 34.

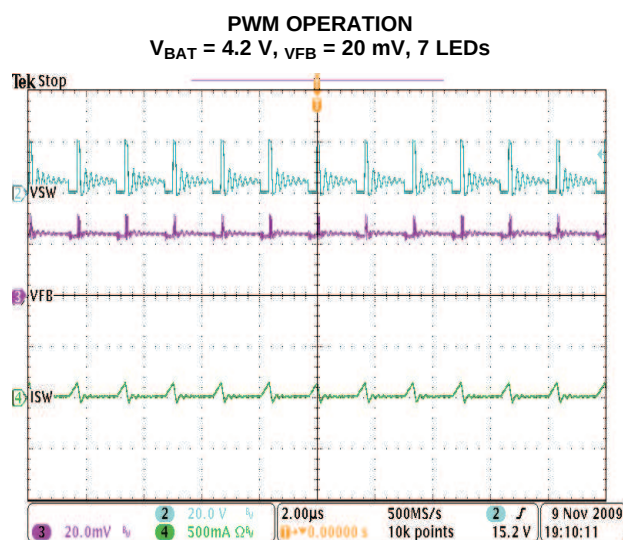


Figure 35.

## TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$ , unless otherwise specified.

**PWM OPERATION**  
 $V_{BAT} = 3\text{ V}$ ,  $V_{FB} = 200\text{ mV}$ , 7 LEDs

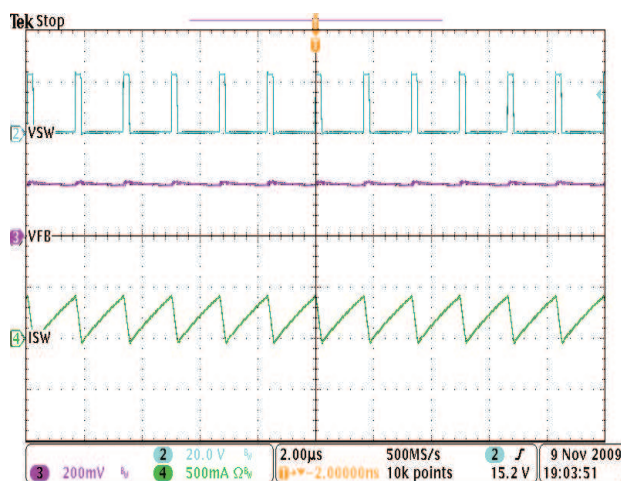


Figure 36.

**PWM OPERATION**  
 $V_{BAT} = 3\text{ V}$ ,  $V_{FB} = 20\text{ mV}$ , 7 LEDs

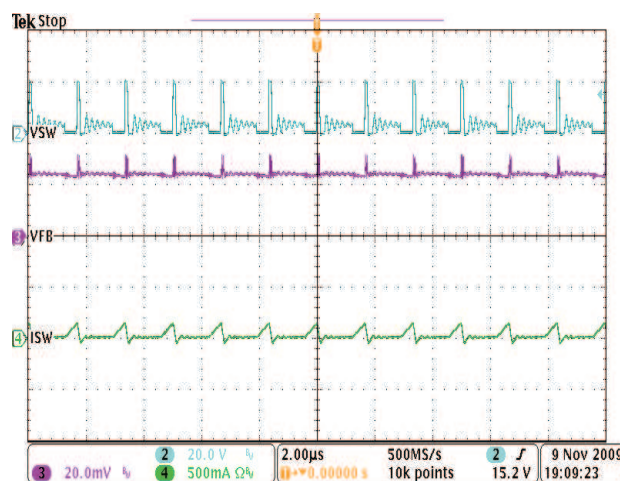


Figure 37.

**PWM DIMMING**  
50% Duty Cycle,  $V_{BAT} = 3.8\text{ V}$ ,  
 $V_{FB} = 200\text{ mV}$ , 7 LEDs

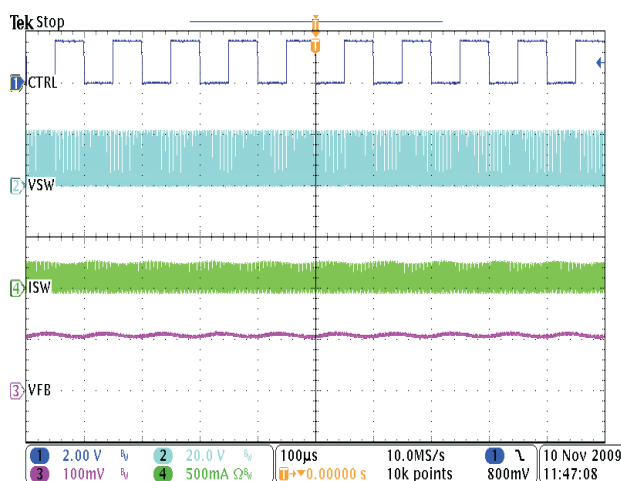


Figure 38.

**OPEN LED PROTECTION**  
 $V_{BAT} = 3.8\text{ V}$ ,  $V_{FB} = 200\text{ mV}$ ,  
7 LEDs (#162)

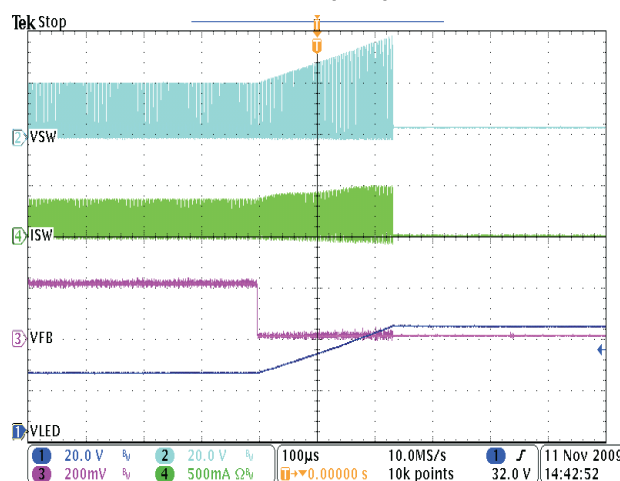


Figure 39.

## TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$ , unless otherwise specified.

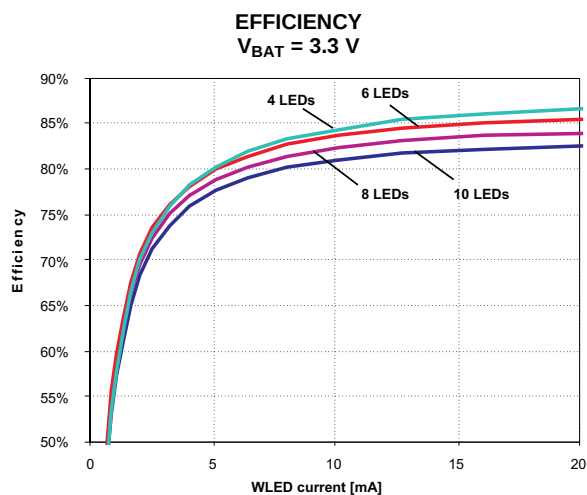


Figure 40.

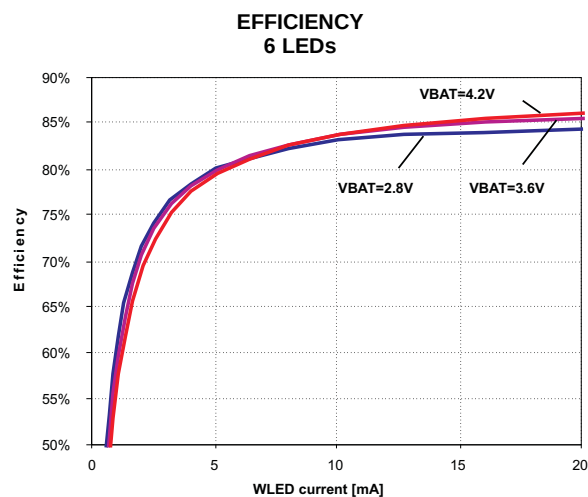


Figure 41.

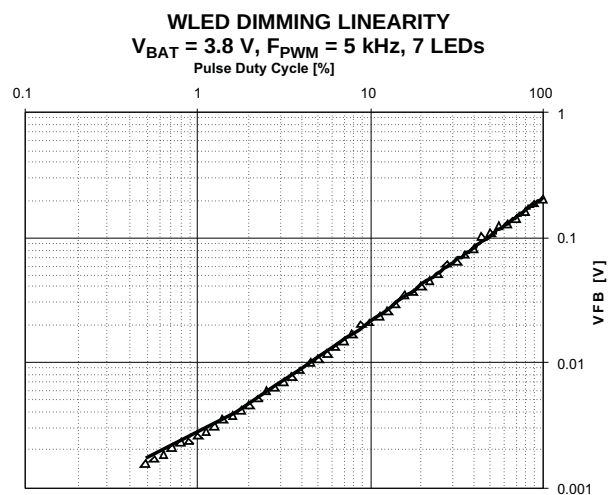


Figure 42.

## GLOBAL STATE DIAGRAM

During normal operation TPS65200 is either in STANDBY mode or ACTIVE mode, depending on user inputs. In STANDBY mode most functions are turned off to conserve power but the IC can still be accessed through I<sup>2</sup>C bus and the current shunt monitor can be turned on and off. The bias system and main oscillator are turned off in STANDBY mode.

The device enters ACTIVE mode whenever VBUS is asserted or the WLED driver is turned on. In ACTIVE mode the main oscillator and reference system is turned on. The device will remain in ACTIVE mode as long as VBUS remains high and/or the WLED driver is enabled.

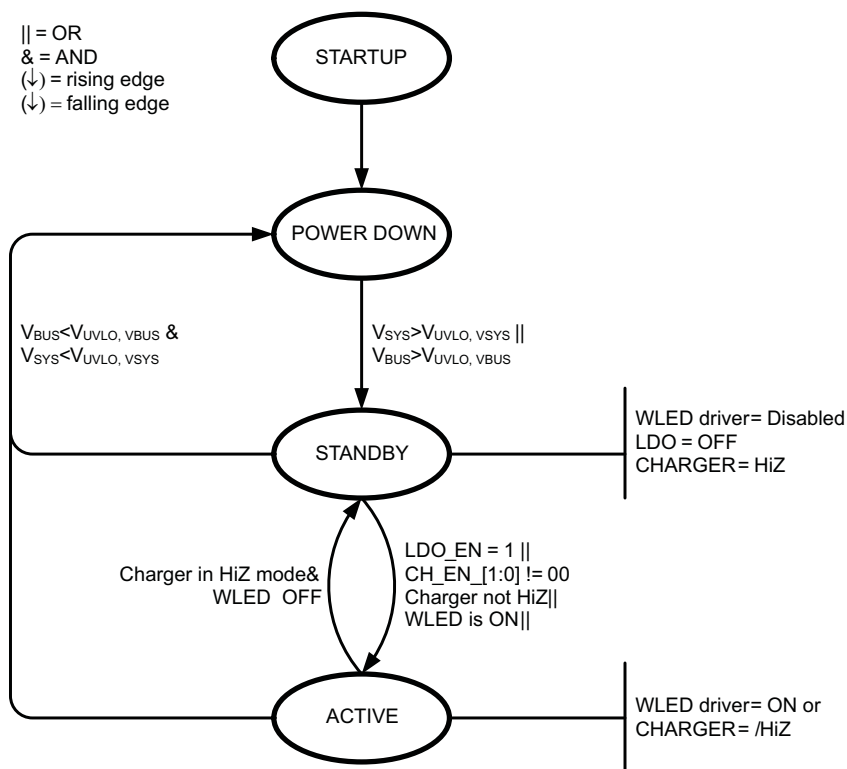


Figure 43. Global State Diagram

## LED DRIVER OPERATION

The TPS65200 offers a high efficiency, high output voltage boost converter designed for driving up to 10 white LED in series. The serial LED connection provides even illumination by sourcing the same output current through all LEDs, eliminating the need for expensive factory calibration. The device integrates 40-V/0.7-A switch FET and operates in pulse width modulation (PWM) with 600-kHz fixed switching frequency. For operation see the block diagram.

The LED driver can be enabled either through the CTRL pin or the WLED\_EN bit in the CONTROL register. The CTRL input is edge sensitive and should be pulled low at power-up. The CTRL pin allows PWM dimming of the LEDs whereas the WLED\_EN bit offers simple ON/OFF control only. The WLED\_EN bit has priority over the CTRL pin and when set to 1, the CTRL pin is ignored. If WLED\_EN is set to 0 and the CTRL pin is low for > 2.5 ms, the WLED driver is shut down.

The feedback loop regulates the FB pin voltage to the reference set by the VFB[4:0] bits in the WLED register with a default setting of 200 mV. If any fault occurs during normal operation the driver is disabled, WLED\_EN bit is reset to 0 and the driver is put into FAULT state until the CTRL pin has been low for > 2.5 ms. The state diagram for the WLED driver is shown in Figure 44.

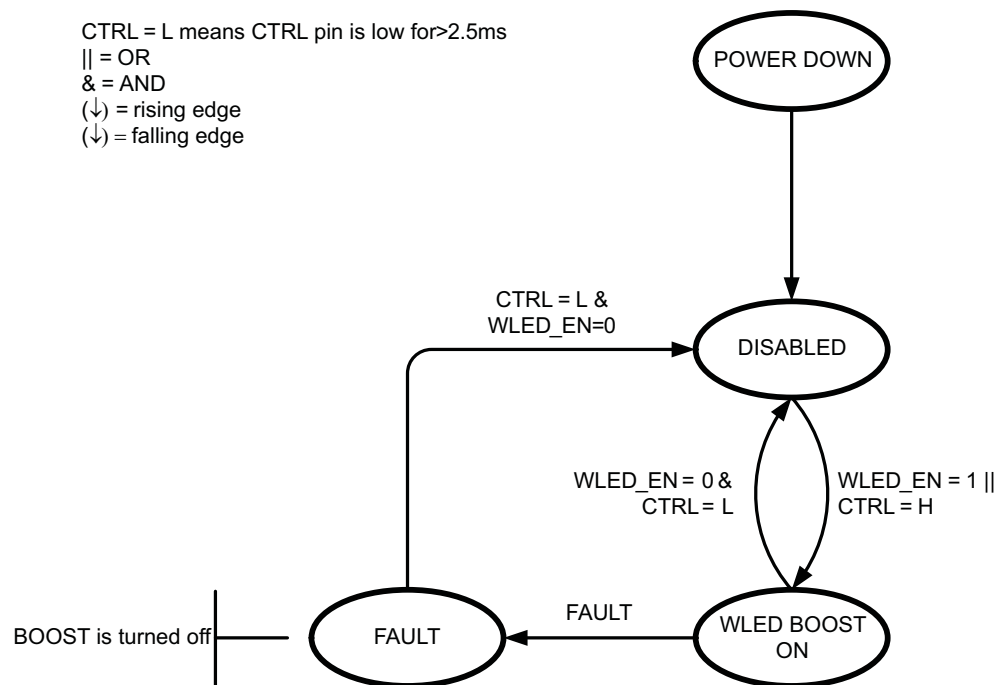


Figure 44. State Diagram for WLED Driver

### Under Voltage Lockout

An under voltage lockout circuit prevents operation of the WLED driver at input voltages (CSOUT pin) below 2.2 V. When the input voltage is below the under voltage threshold, the driver is shutdown and the internal switch FET is turned off. If the input voltage rises by 70 mV above the under voltage lockout hysteresis, the WLED driver restarts. An internal thermal shutdown turns off the device when the typical junction temperature of 165°C is exceeded. The device is released from shutdown automatically when the junction temperature decreases by 10°C.

### Shutdown

To minimize current consumption the WLED driver is shutdown when the WLED\_EN bit is low and the CTRL pin is pulled low for more than 2.5 ms. Although the internal FET does not switch in shutdown, there is still a DC current path between the input and the LEDs through the inductor and Schottky diode. The minimum forward voltage of the LED array must exceed the maximum input voltage to ensure that the LEDs remain off in shutdown. However, in the typical application with two or more LEDs, the forward voltage is large enough to reverse bias the Schottky and keep leakage current low.

### Soft-Start Circuit

Soft-start circuitry is integrated into the WLED driver to avoid a high inrush current during start-up. After the device is enabled, the voltage at FB pin ramps up to the reference voltage in 32 steps, each step takes 213 μs. This ensures that the output voltage rises slowly to reduce the input current. Additionally, for the first 5 ms after the COMP voltage ramps, the current limit of the switch is set to half of the normal current limit specification. During this period, the input current is kept below 400 mA (typical).

### Open LED Protection

Open LED protection circuitry prevents IC damage as the result of white LED disconnection. The TPS65200 monitors the voltage at the SWL pin during each switching cycle. The circuitry turns off the switch FET and shuts down the WLED driver as soon as the SWL voltage exceeds the  $V_{OVP}$  threshold for eight clock cycles. As a result, the output voltage falls to the level of the input supply. The WLED driver remains in shutdown mode until it is enabled by toggling the CTRL pin or the WLED\_EN bit of the CTRL register.

## Current Program

The FB voltage is regulated to a low 200-mV reference voltage. The LED current is programmed externally using a current-sense resistor in series with the LED string. The value of the RSET is calculated using [Equation 1](#).

$$I_{LED} = \frac{V_{FB}}{R_{SET}} \quad (1)$$

Where:

1.  $I_{LED}$  = output current of LEDs
2.  $V_{FB}$  = regulated voltage of FB
3.  $R_{SET}$  = current sense resistor

The output current tolerance depends on the FB accuracy and the current sensor resistor accuracy.

## Brightness Dimming

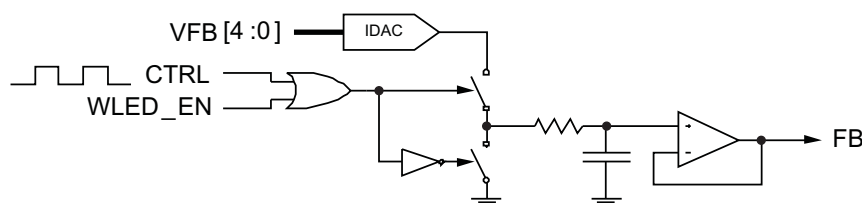
The TPS65200 offers two methods of LED brightness dimming. When the CTRL pin is constantly high, the FB voltage is regulated to the value set in the WLED register which ranges from 0 mV to 200 mV and is divided into 32 steps. For applications requiring higher dimming resolution a PWM signal can be applied to the CTRL pin to reduce this regulation voltage and dim LED brightness. The relationship between the duty cycle and FB voltage is given by [Equation 2](#).

$$V_{FB} = \text{duty cycle} \cdot V_{FB}[4:0] \quad (2)$$

Where:

1. Duty = duty cycle of the PWM signal
2.  $V_{FB}[4:0]$  = internal reference voltage, default = 200 mV

The IC chops up the internal reference voltage at the duty cycle of the PWM signal and filters it by an internal low pass filter. The output of the filter is connected to the error amplifier as the reference voltage for the FB pin regulation. Therefore, although a PWM signal is used for brightness dimming, only the WLED DC current is modulated, which is often referred to as analog dimming. This eliminates the audible noise which often occurs when the LED current is pulsed in replica of the frequency and duty cycle of PWM control. The regulation voltage itself is independent of the PWM logic voltage level which often has large variations.



**Figure 45. WLED Analog Dimming Circuit**

## Inductor Over Current Protection

The over current limit in the boost converter limits the maximum input current and thus maximum input power for a given input voltage. Maximum output power is less than maximum input power due to power conversion losses. Therefore, the current limit setting, input voltage, output voltage and efficiency can all change maximum current output. The current limit clamps the peak inductor current and the maximum DC output current equals the current limit minus half of the peak-peak current ripple. The ripple current is a function of switching frequency, inductor value and duty cycle. [Equation 3](#) through [Equation 5](#) are used to determine the maximum output current.

$$D = 1 - \frac{V_{IN}}{V_{OUT}} \quad (3)$$

Where:

1. D = duty cycle of the boost converter
2.  $V_{IN}$  = Input voltage

3.  $V_{OUT}$  = Output voltage of the boost converter. It is equal to the sum of  $V_{FB}$  and the voltage drop across LEDs.

$$I_{PP} = \frac{V_{IN} \cdot D}{L \cdot f_s} \quad (4)$$

Where:

1.  $I_{PP}$  = inductor peak to peak ripple
2.  $L$  = inductor value
3.  $f_s$  = switching frequency

$$I_{OUT(MAX)} = \frac{V_{IN} \cdot \left( I_{LIM} - \frac{I_{PP}}{2} \right) \cdot \eta}{V_{OUT}} \quad (5)$$

Where:

1.  $I_{OUT(MAX)}$  = maximum output current of the boost converter
2.  $I_{LIM}$  = over current limit
3.  $\eta$  = efficiency

For instance, for  $V_{IN} = 3\text{ V}$ , 7 LEDs output equivalent to  $V_{OUT}$  of 23 V, an inductor value of 22  $\mu\text{H}$ , a current limit of 700 mA, and an efficiency of 85%, the maximum output current is ~65 mA.

## CHARGE MODE OPERATION

For current limited power source, such as a USB host or hub, the high efficiency converter is critical in fully utilizing the input power capacity and quickly charging the battery. Due to the high efficiency in a wide range of the input voltage and battery voltage, the switching mode charger is a good choice for high speed charging with less power loss and better thermal management.

The TPS65200 is a highly integrated synchronous switch-mode charger with reverse boost function for USB OTG support, featuring integrated MOSFETs and small external components, targeted at extremely space-limited portable applications powered by 1-cell Li-ion or Li-polymer battery pack.

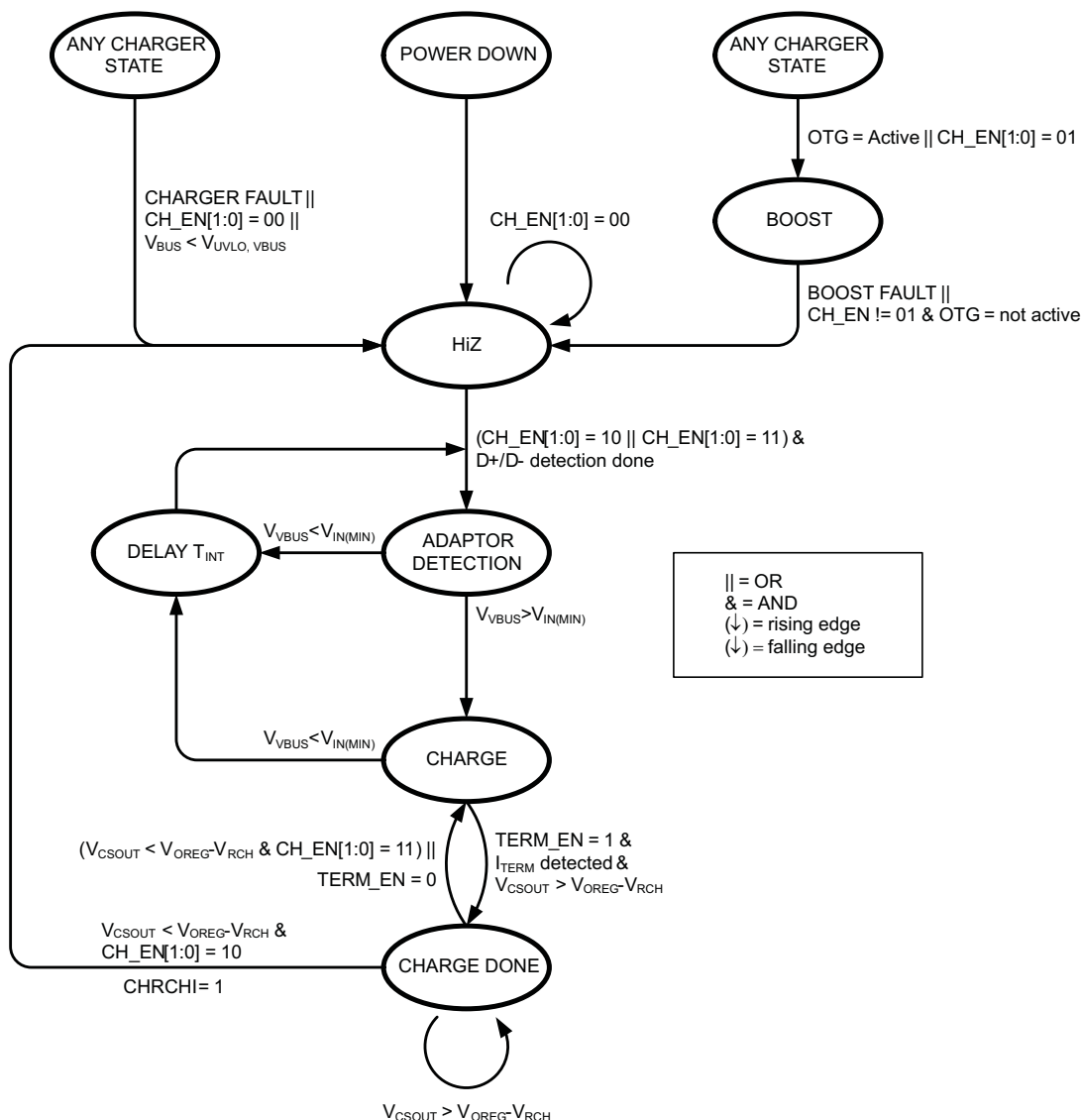


Figure 46. State Diagram of USB Charger Circuit

The TPS65200 has three operation modes: charge mode, boost mode, and high impedance mode. In charge mode, the TPS65200 supports a precision Li-ion or Li-polymer charging system for single-cell applications. In boost mode, TPS65200 will boost the battery voltage to VBUS for powering attached OTG devices. In high impedance mode, the TPS65200 charger stops charging or boosting and operates in a mode with very low current from VBUS or battery, to effectively reduce the power consumption when the portable device is in standby mode. Through carefully designed internal control circuits, TPS65200 achieves smooth transition between different operation modes.

The global state diagram of the charger is shown in Figure 46 and the detailed charging algorithm in Figure 47. HiZ mode is the default state of the charger where Q1, charger PWM and boost operation is turned off. If any fault occurs during charging, the CH\_EN[1:0] bits in the CONTROL register are reset to 00b (OFF), fault bits are set in the INT2 register, an interrupt is issued on the INT pin, and HiZ mode is entered. Charging is re-initiated by either host control or automatically if VBUS is power cycled.

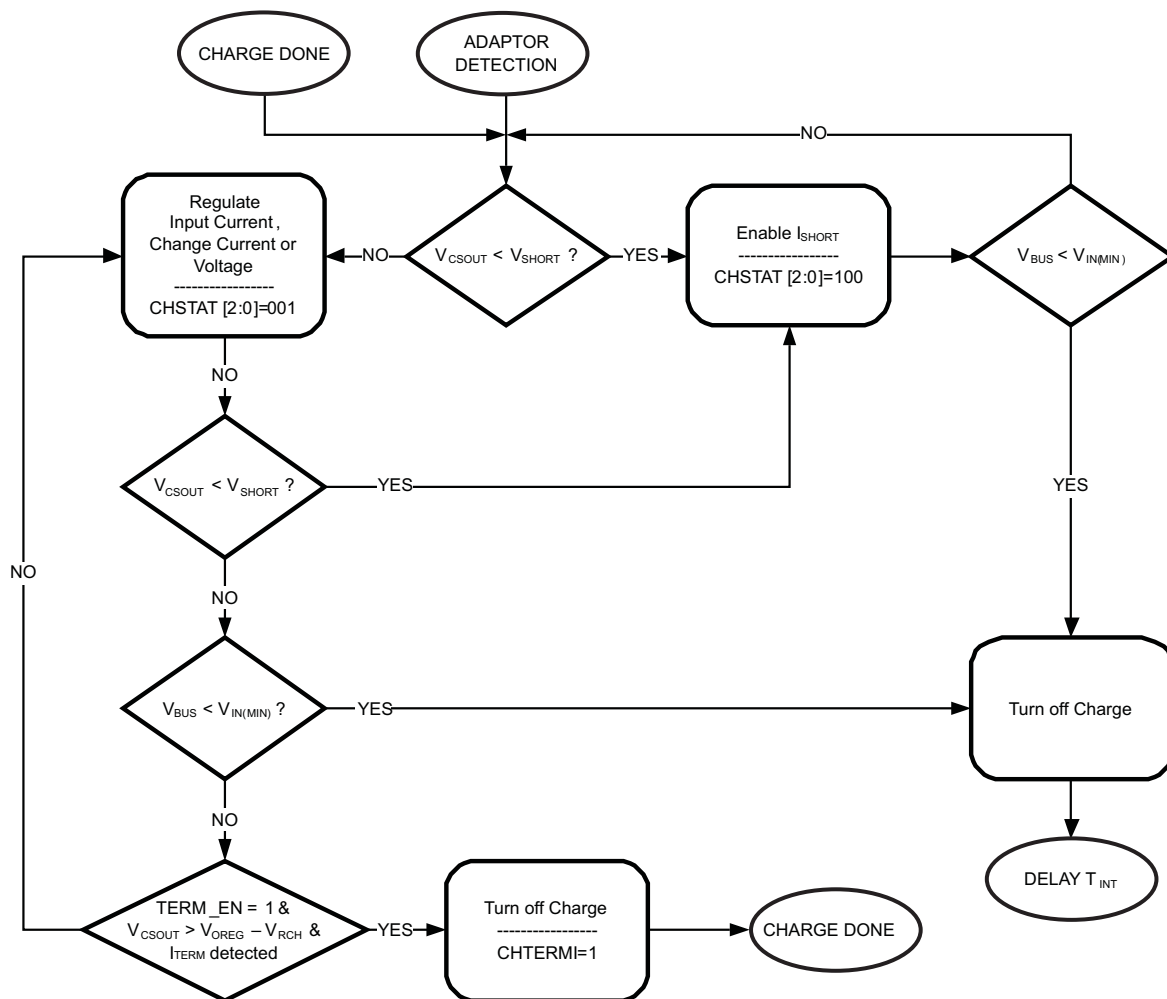


Figure 47. Detailed Charging Flow Chart

### Input Current Limiting and D+/D- Detection

By default the VBUS input current limit is set to 500 mA. When VBUS is asserted the TPS65200 performs a charger source identification to determine if it is connected to a USB port or dedicated charger. This detection is performed 200 ms after VBUS is asserted to ensure the USB plug has been fully inserted before identification is performed. If a dedicated charger is detected the input current limit is increased to 975 mA, otherwise the current limit remains at 500 mA, unless changed by the user.

Automatic detection is performed only if VIO is below 0.6 V to avoid interfering with the USB transceiver which may also perform D+/D- detection when the system is running normally. However, D+/D- can be initiated at any time by the host by setting the DPDM\_EN bit in the CONTROL register to 1. After detection is complete the DPDM\_EN bit is automatically reset to 0 and the detection circuitry is disconnected from the DP DM pins to avoid interference with USB data transfer.

The input current limit can also be set through the I<sup>2</sup>C interface to 100 mA, 500 mA, 975 mA, or no limit by writing to the CONFIG\_B register. The effective current limit will be the higher of the D+/D- detection result and the IIN\_LIMIT[1:0] setting in CONFIG\_A register. Whenever VBUS drops below the UVLO threshold IIN\_LIMIT[1:0] is reset to 100-mA setting to avoid excessive current draw from an unknown USB port.

Once the input current reaches the input current limiting threshold, the charge current is reduced to keep the input current from exceeding the programmed threshold. The host can choose to ignore the D+/D- detection result by setting the LMTSEL bit of the CONFIG\_A register to 1.

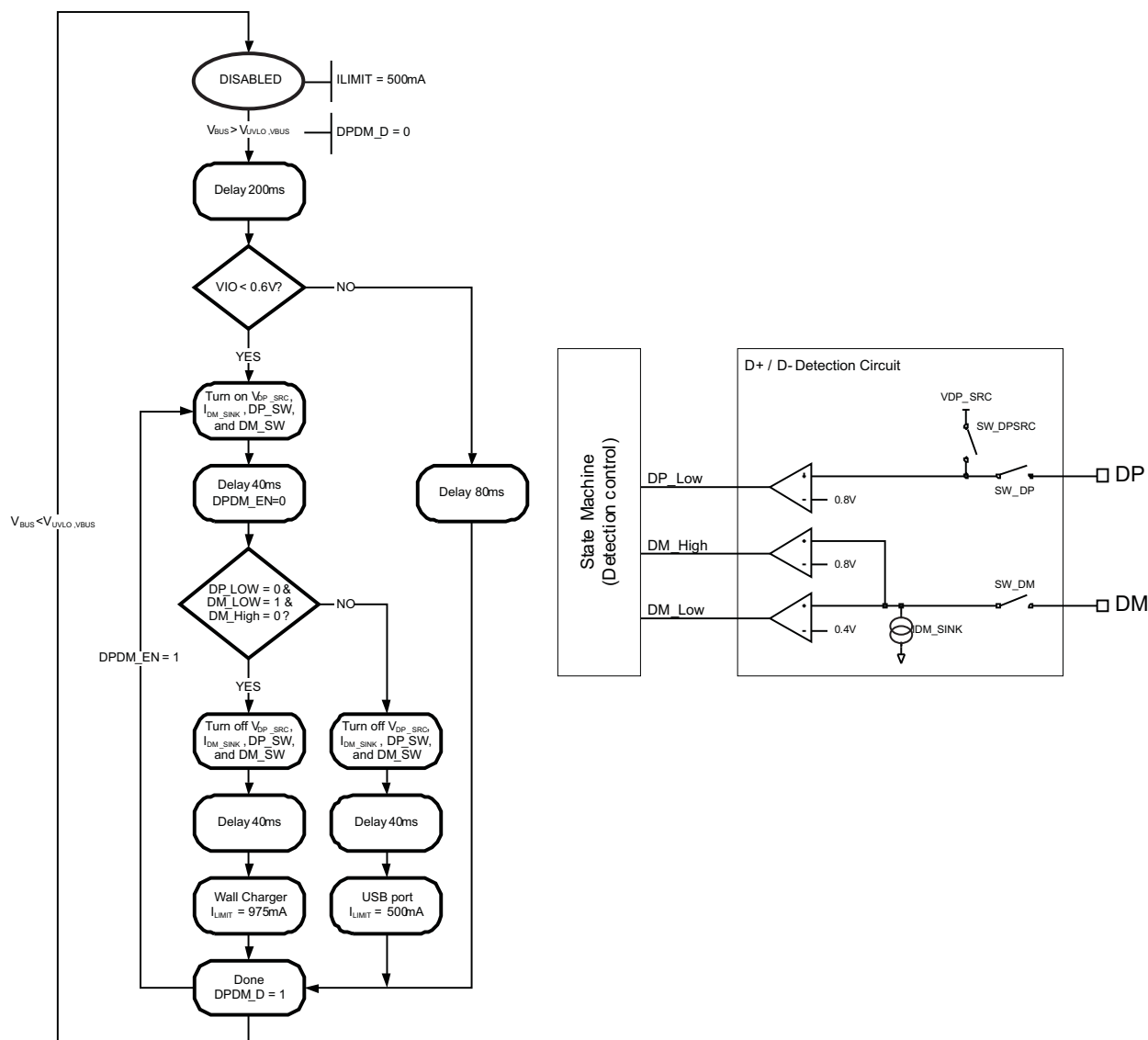


Figure 48. Adaptor Identification Algorithm and Block Diagram

### Bad Adaptor Detection/Rejection (CHBADI)

At the beginning of the charge cycle, the IC will perform the bad adaptor detection by applying a current sink to VBUS. If  $V_{VBUS}$  is higher than  $V_{IN(MIN)}$  for 30 ms, the adaptor is good and the charge process will begin. However, if  $V_{VBUS}$  drops below  $V_{IN(MIN)}$ , a bad adaptor is detected. Then, the IC will disable the current sink, issue an interrupt and set the CHBADI interrupt in the INT2 register. After a delay of  $T_{INT}$  (2s), the IC will repeat the adaptor detection process, as shown in Figure 50.

If the battery voltage is high ( $> 3.8$  V) it is possible that the input voltage drops below the battery voltage during adaptor rejection test. In this case the reverse protection will kick-in and disable the charger. Also note that the 30-mA current sink is turned on for 30 ms only. If the input capacitance is  $> 500$   $\mu$ F (not recommended) the adaptor may be accepted although it is not capable of providing 30-mA of current. In these cases the VDPPM loop will limit the charging current to maintain the input voltage.

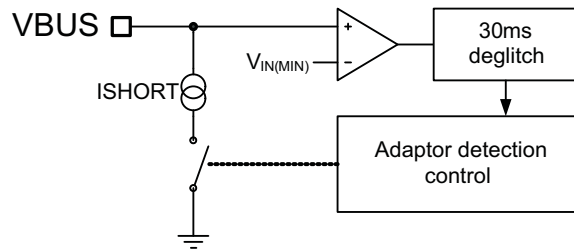


Figure 49. Bad Adaptor Detection Circuit

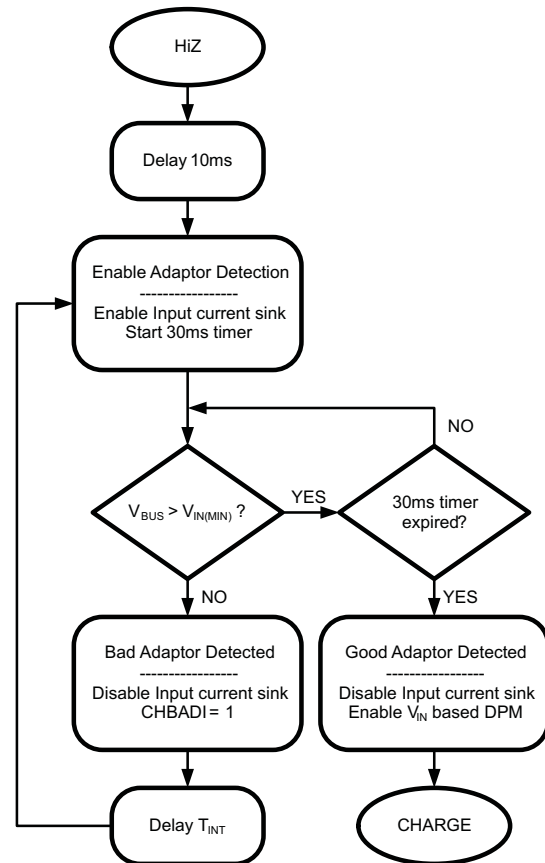


Figure 50. Bad Adaptor Detection Flow-Chart

### Input Current Limiting at Start Up

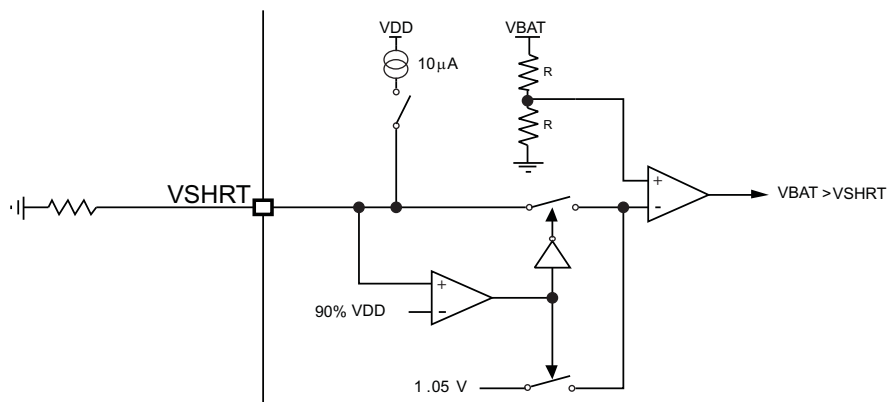
The LOW\_CHG bit is automatically set when VBUS is asserted to limit the charge current to 150 mA. This ensures that a battery cannot be charged with high currents without host control.

### Charge Profile

In charge mode, TPS65200 has five control loops to regulate input voltage, input current, charge current, charge voltage and device junction temperature. During the charging process, all five loops are enabled and the one that is dominant will take over the control. The TPS65200 supports a precision Li-ion or Li-polymer charging system for single-cell applications. Figure 52 indicates a typical charge profile without input current regulation loop and it is similar to the traditional CC/CV charge curve, while Figure 53 shows a typical charge profile when input current limiting loop is dominant during the constant current mode, and in this case the charge current is higher than the input current so the charge process is faster than the linear chargers. For TPS65200, the input current limits, the charge current, termination current, and charge voltage are all programmable using I<sup>2</sup>C interface.

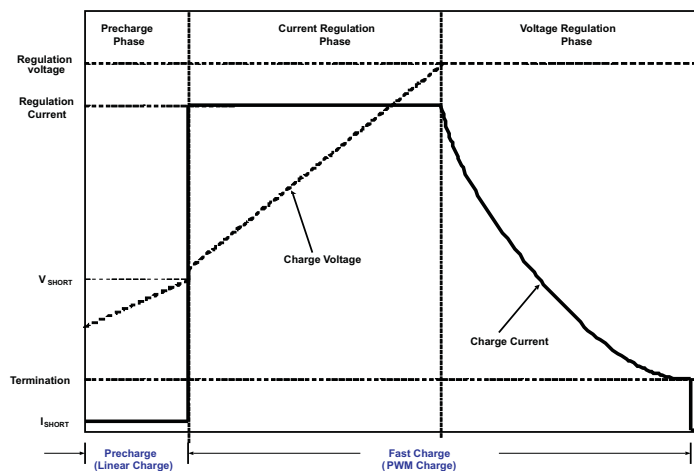
### Precharge to Fast Charge Threshold (VSHORT)

A deeply discharged battery ( $V_{BAT} < V_{SHORT}$ ) is charged with a constant current of  $I_{SHORT}$  (typically 30 mA) until the voltage recovers to  $> V_{SHORT}$  at which point fast charging begins. The pre-charge to fast-charge threshold has a default value of 2.1 V and can be adjusted by connecting a resistor from the VSHORT pin to ground. An internal current source forces a 10-μA current into the resistor and the resulting voltage is compared to half the battery voltage to determine if the battery is deeply discharged or shorted. Therefore the voltage on the VSHORT pin equals half of  $V_{SHORT}$  threshold. For example a 100-kΩ resistor connected from VSHORT to GND results in a 2-V precharge to fast charge transition point. If the VSHORT pin is left floating or is shorted to the VDD pin, an internal reference voltage of 1.05 V is used resulting in a 2.1-V pre-charge to fast-charge threshold.



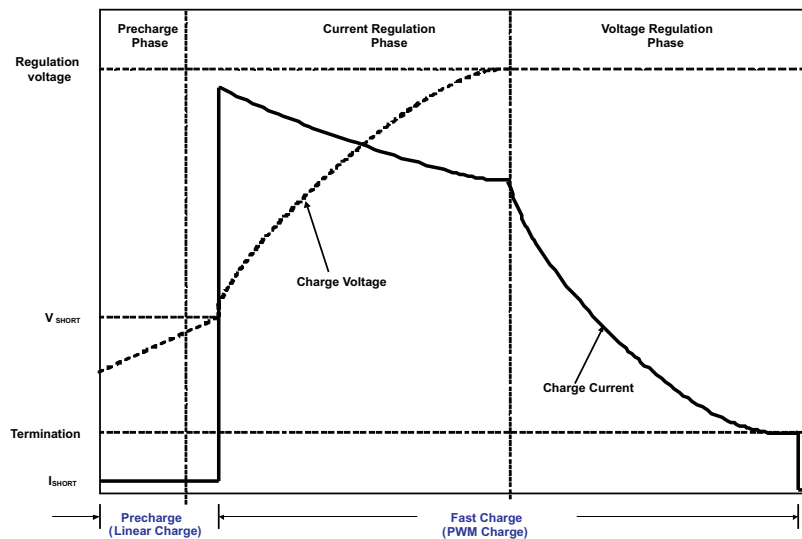
VSHORT can be adjusted by an external resistor. Note that the VSHRT pin voltage equals half VSHORT threshold. When VSHRT pin is left floating or is tied to VDD, an internal reference of 1.05 V is used resulting in a 2.1-V pre-charge to fast-charge transition threshold.

Figure 51. Pre-Charge to Fast-Charge Transition Threshold (VSHORT)



The input current remains constant during current regulation phase.

Figure 52. Typical Charging Profile of TPS65200 Without Input Current Limit



The charging current during current regulation phase decreases as battery voltage increases. This mode ensures fastest charging of the battery without exceeding the adaptor current limit.

**Figure 53. Typical Charging Profile of TPS65200 With Input Current Limit**

### PWM Controller in Charge Mode

The TPS65200 provides an integrated, fixed 3-MHz frequency voltage-mode controller with feed-forward function to regulate charge current or voltage. This type of controller is used to help improve line transient response, thereby simplifying the compensation network used for both continuous and discontinuous current conduction operation. The voltage and current loops are internally compensated using a Type-III compensation scheme that provides enough phase margin for stable operation, allowing the use of small ceramic capacitors with very low ESR. There is a 0.5-V offset on the bottom of the PWM ramp to allow the device to operate between 0% to 99.5% duty cycles.

The TPS65200 has two back-to-back common-drain N-channel MOSFETs at the high side and one N-channel MOSFET at the low side. An input N-MOSFET (Q1) prevents battery discharge when  $V_{BUS}$  is lower than  $V_{CSOUT}$ . The second high-side N-MOSFET (Q2) behaves as the switching control switch. A charge pump circuit is used to provide gate drive for Q1, while a boot strap circuit with external boot-strap capacitor is used to boost up the gate drive voltage for Q2.

Cycle-by-cycle current limit is sensed through the internal sense MOSFETs for Q2 and Q3. The threshold for Q2 is set to a nominal 1.9-A peak current. The low-side MOSFET (Q3) also has a current limit that decides if the PWM controller will operate in synchronous or non-synchronous mode. This threshold is set to 100mA and it turns off the low-side N-channel MOSFET (Q3) before the current reverses, preventing the battery from discharging. Synchronous operation is used when the current of the low-side MOSFET is greater than 100 mA to minimize power losses.

### Battery Charging Process

During precharge phase, while the battery voltage is below the  $V_{SHORT}$  threshold, the TPS65200 applies a short-circuit current,  $I_{SHORT}$ , to the battery. When the battery voltage is above  $V_{SHORT}$  and below  $V_{OREG}$ , the charge current ramps up to fast charge current,  $I_{OCHARGE}$ , or a charge current that corresponds to the input current of  $I_{IN\_LIMIT}$ . The slew rate for fast charge current is controlled to minimize the current and voltage over-shoot during transient. Both the input current limit (default at 100 mA),  $I_{IN\_LIMIT}$ , and fast charge current,  $I_{OCHARGE}$ , can be set by the host. Once the battery voltage is close to the regulation voltage,  $V_{OREG}$ , the charge current is tapered down as shown in Figure 52. The voltage regulation feedback occurs by monitoring the battery-pack voltage between the CSOUT and PGND pins. TPS65200 is a fixed single-cell voltage version, with adjustable regulation voltage (3.5 V to 4.44 V) programmed through I<sup>2</sup>C interface.

The TPS65200 monitors the charging current during the voltage regulation phase. Once the termination threshold,  $I_{TERM}$ , is detected and the battery voltage is above the recharge threshold, the TPS65200 terminates charge. The termination current level is programmable and charge termination is disabled by default. To enable the charge current termination, the host can set the charge termination bit `TERM_EN` of `CONFIG_C` register to 1. Refer to I<sup>2</sup>C section for details.

A new charge cycle is initiated when one of the following events occur:

- VBUS is power-cycled.
- `CH_EN[1:0]` = 11b and the battery voltage drops below the recharge threshold (`TERM_EN` = 1).
- The `RESET` bit is set (host controlled).
- The device is in CHARGE DONE state (see [Figure 46](#)) and the `TERM_EN` bit is set from 1 to 0.

### Thermal Regulation and Protection

During the charging process, to prevent overheating of the chip, TPS65200 monitors the junction temperature,  $T_J$ , of the die and begins to taper down the charge current once  $T_J$  reaches the thermal regulation threshold,  $T_{CF}$ . The charge current will be reduced to zero when the junction temperature increases about 10°C above  $T_{CF}$ . At any state, if  $T_J$  exceeds  $T_{SHTDWN}$ , TPS65200 will suspend charging and enter HiZ state. Charging will resume after  $T_J$  falls 10°C below  $T_{SHTDWN}$ .

### Safety Timer in Charge and Boost Mode (CH32MI, BST32SI)

The TPS65200 charger hosts a safety timer that stops any boost or charging action if host control is lost. The timer is started when the `CH_EN[1:0]` bits are set to anything different from 00 and is continuously reset by any valid I<sup>2</sup>C command. If the timer exceeds 32 s and boost mode is enabled (`CH_EN[1:0]` = 01b), the boost is disabled, `CH_EN[1:0]` is set to 00b, boost time-out fault is indicated in the `INT2` register, and an interrupt is issued. Similarly, once the timer exceeds 32 minutes and the charger is enabled (`CH_EN[1:0]` = 10b or 11b), the charger is disabled, `CH_EN[1:0]` is set to 00b, charger time-out fault is indicated in `INT2` register and an interrupt is issued. Time-out faults affect `CH_EN[1:0]` bits only and not charger parameters. The safety timer flow chart is shown in [Figure 54](#).

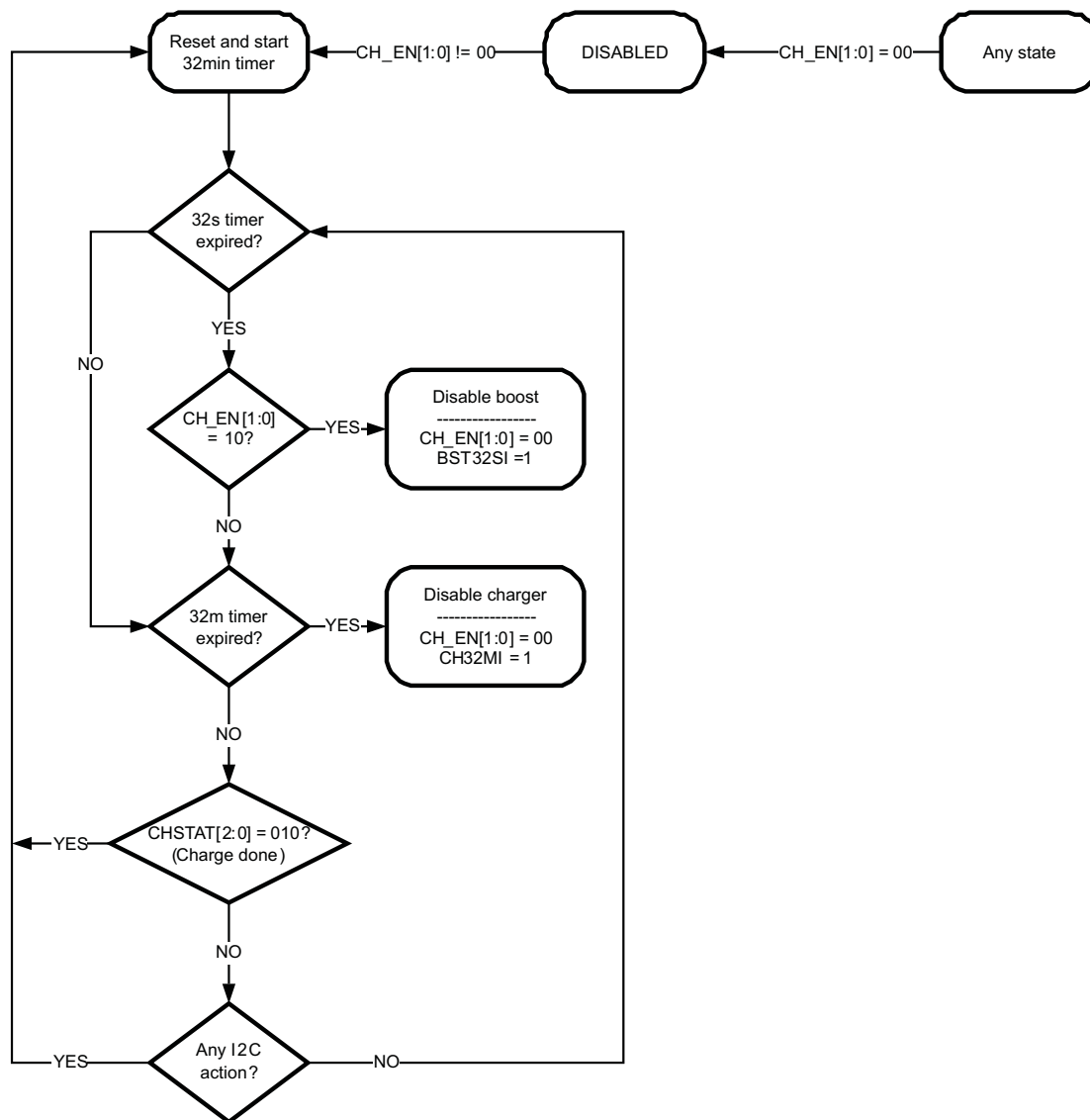


Figure 54. Timer Flow Chart for TPS65200 Charger

## Input Voltage Protection in Charge Mode

### Input Over-Voltage Protection (VBUSOVPI)

The TPS65200 provides a built-in input over-voltage protection to protect the device and other components against damage if the input voltage (voltage from VBUS to PGND) gets too high. When an input over-voltage condition is detected, the TPS65200 turns off the PWM converter, sets the VBUSOVPI bit in the INT1 register and issues an interrupt. Once  $V_{VBUS}$  drops below the input over-voltage exit threshold, the fault is cleared and charge process resumes.

### Reverse Current Protection (CHRVPI)

The TPS65200 charger enters HiZ state if the voltage on VBUS pin falls below  $V_{CSOUT} + V_{REV}$ , and  $V_{BUS}$  is still higher than the poor source detection threshold,  $V_{IN(MIN)}$ . The CHRVPI bit is set in the INT2 register and an interrupt is issued. This feature prevents draining the battery during the absence of  $V_{BUS}$ . In HiZ mode, both the reverse blocking switch Q1 and PWM are turned off.

### ***Input Voltage Based Dynamic Power Management (CHDPMI)***

During normal charging process, if the input power source is not able to support the charging current,  $V_{BUS}$  voltage will decrease. Once  $V_{VBUS}$  drops to  $V_{IN\_LOW}$  (default 4.36 V), the charge current will taper down to prevent further drop of  $V_{BUS}$ . This feature makes the IC compatible with adaptors with different current capabilities. Whenever the VDPM loop activates, the CHDPMI interrupt is set in the INT2 register and the INT pin is pulled low. The CHDPMI interrupt is delayed by 32 ms to prevent the interrupt to occur when the charging source is removed.

### **Battery Protection in Charge Mode**

#### ***Battery Charge Current Limiting***

Whenever a valid power source is connected to the charger, the LOW\_CHG bit of the CONFIG\_C register is set to 1 which limits the charging current to 150 mA. Once the host detects that that charging source has been inserted it needs to reset the LOW\_CHG bit to 0 to achieve a higher charging current. This feature prevents charging of a battery at high currents when system voltage is too low for the system to boot.

#### ***Output Over-Voltage Protection (CHBATOVPI)***

The TPS65200 provides a built-in over-voltage protection to protect the device and other components against damage if the battery voltage gets too high, as when the battery is suddenly removed. When an over-voltage condition is detected, TPS65200 turns off the PWM converter, sets the CHBATOVPI bit in the INT2 register, issues an interrupt, and enters HiZ mode. Once  $V_{CSOUT}$  drops to the battery over-voltage exit threshold, charging resumes.

#### ***Battery Short Protection***

During the normal charging process, if the battery voltage is lower than the short-circuit threshold,  $V_{SHORT}$ , the charger will operate in short circuit mode with a lower charge rate of  $I_{SHORT}$ .

### **Charge Status Output, STAT Pin**

The STAT pin is used to indicate charging status of the IC and its behavior can be controlled by setting the STAT\_EN bits of the CONTROL register. In AUTO mode, STAT is pulled low during charging and is high-impedance otherwise. STAT pin can also be forced low or to HiZ state by setting the STAT\_EN bits accordingly. The STAT pin has enough pull-down strength to drive a LED and can be used for visual charge status indication.

## **BOOST MODE OPERATION**

In 32 second mode, when CH\_EN[1:0] = 01 in CONTROL register, TPS65200 operates in boost mode and delivers power to VBUS from the battery. In normal boost mode, TPS65200 converts the battery voltage (2.5V to 4.5 V) to VBUS-B (5 V) and delivers a current as much as IBO (200 mA) to support other USB OTG devices connected to the USB connector. Boost mode can also be enabled through the OTG pin. By default the OTG pin is disabled and can be enabled by setting the OTG\_EN bit to 1. The polarity of the OTG pin is user programmable through the OTG\_PL bit. Both bits are located in the CONFIG\_C register. The OTG pin allows the USB transceiver to take control of the boost function without involvement of the main processor.

### **PWM Controller in Boost Mode**

Similar to charge mode operation, in boost mode, the TPS65200 provides an integrated, fixed 3-MHz frequency voltage-mode controller to regulate output voltage at PMID pin ( $V_{PMID}$ ). The voltage control loop is internally compensated using a Type-III compensation scheme that provides enough phase margin for stable operation with a wide load range and battery voltage range.

In boost mode, the input N-MOSFET (Q1) prevents battery discharge when VBUS pin is over loaded. Cycle-by-cycle current limit is sensed through the internal sense MOSFET for Q3. The threshold for Q3 is set to a nominal 1.0-A peak current. The upper-side MOSFET (Q2) also has a current limit that decides if the PWM controller will operate in synchronous or non-synchronous mode. This threshold is set to 75 mA and it turns off the high-side N-channel MOSFET (Q2) before the current reverses, preventing the battery from charging. Synchronous operation is used when the current of the high-side MOSFET is greater than 75 mA to minimize power losses.

## Boost Start Up

To prevent the inductor saturation and limit the inrush current, a soft-start control is applied during the boost start up.

## PFM Mode at Light Load

In boost mode, TPS65200 will operate in pulse skipping mode (PFM mode) to reduce the power loss and improve the converter efficiency at light load condition. During boosting, the PWM converter is turned off once the inductor current is less than 75 mA; and the PWM is turned back on only when the voltage at PMID pin drops to about 99.5% of the rated output voltage. A unique pre-set circuit is used to make the smooth transition between PWM and PFM mode.

## Safety Timer in Boost Mode (BST32SI)

At the beginning of boost operation, the TPS65200 starts a 32-second timer that is reset by the host through any valid I<sup>2</sup>C transaction to the IC. Once the 32-second timer expires, TPS65200 will turn off the boost converter, issue an interrupt, set the BST32SI bit in the INT3 register, and return to HiZ mode. Fault condition is cleared by POR or reading the INT3 register.

## Protection in Boost Mode

### Output Over-Voltage Protection (BSTBUSOVI)

The TPS65200 provides a built-in over-voltage protection to protect the device and other components against damage if the VBUS voltage gets too high. When an over-voltage condition is detected, TPS65200 turns off the PWM converter, resets CH\_EN[1:0] bits to 00b (OFF), sets the BSTBUSOVI bit in the INT3 register, issues an interrupt, and enters HiZ mode. Once VVBUS drops to the normal level, the boost will start after host sets CH\_EN[1:0] = 01b.

### Output Over-Load Protection (BSTOLI)

The TPS65200 provides a built-in over-load protection to prevent the device and battery from damage when VBUS is over loaded. Once an over load condition is detected, Q1 will operate in linear mode to limit the output current while VPMID is kept in voltage regulation. If the over load condition lasts for more than 30 ms, the over-load fault is detected. When an over-load condition is detected, TPS65200 turns off the PWM converter, resets CH\_EN[1:0] bits to 00b (OFF), sets the BSTOLI bit in the INT3 register, and issues an interrupt. The boost will not start until the host sets CH\_EN[1:0] = 01b or the OTG pin is toggled.

### Battery Voltage Protection (BSTLOWVI, BSTBATOVI)

During boosting, when battery voltage is above the battery over voltage threshold,  $V_{BATMAX}$ , or below the minimum battery voltage threshold,  $V_{BATMIN}$ , TPS65200 will turn off the PWM converter, reset CH\_EN[1:0] bits to 00b (OFF), set the BSTLOWVI or BSTBATOVI bit in the INT3 register, and issues an interrupt. Once the battery voltage goes back to the normal level, the boost will start if the host sets CH\_EN[1:0] = 01b or the OTG pin is toggled.

## HIGH IMPEDANCE MODE

When CH\_EN[1:0] bits in the CONTROL register are set to 00b, TPS65200 will operate in high impedance mode, with the impedance looking into VBUS pin higher than 500k $\Omega$ .

## HV LDO

TPS65200 provides a 4.9-V LDO that is powered off the VBUS input. The LDO is enabled whenever  $V_{VBUS} > V_{UVLO}$  (3.3 V) and disabled when  $V_{VBUS} > V_{OVP-IN\_USB}$  (6.5 V). LDO output voltage follows VBUS for  $V_{VBUS} < 4.9$  V and is regulated to 4.9 V when  $V_{VBUS} > 4.9$  V. In any case output current is limited to 100 mA. The LDO can also be disabled by the host by setting the LDO\_EN bit of the CONTROL register to 0. An operational flow chart of the LDO enable is shown in [Figure 55](#).

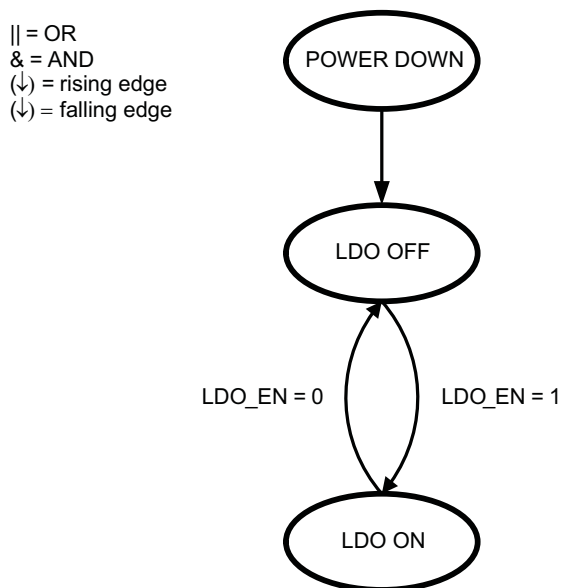


Figure 55. State Diagram for the HV LDO

## INTERRUPT PIN

The interrupt pin is used to signal any fault condition to the host processor. Whenever a fault occurs in the IC the corresponding fault bit is set in the INT1, INT2, or INT3 register, and the open-drain output is pulled low. The INT pin is released (returns to HiZ state) if any of the INT1, INT2, INT3 registers is accessed by the host but fault bits are cleared only by reading the INTx register containing the bit. However, if a failure persists, the corresponding interrupt bit remains set but no new interrupt is issued. The TSD bit (thermal shutdown) is auto cleared which means that the bit is reset to 0 automatically after the chip has cooled down below the thermal shutdown release threshold.

The MASK1, MASK2, and MASK3 registers are used to mask certain events or group of events from generating interrupts. The MASKx settings affect the INT pin only and have no impact on protection and monitor circuits themselves.

## CURRENT SHUNT MONITOR

TPS65230 offers an integrated high-precision current shunt monitor to measure battery charging and discharging currents. The inputs of a low-offset amplifier are connected across an external low-value shunt resistor. This shunt voltage is gained up by a factor of 25 and added to a reference voltage connected to the VZERO terminal.

$V_{SHUNT} > V_{ZERO}$  for currents flowing into the battery and  $V_{SHUNT} < V_{ZERO}$  for currents flowing out of the battery. The reference voltage is buffered by a low-offset, high impedance input buffer.

$$V_{SHUNT} = 25 \cdot (V_{CSIN} - V_{CSOUT}) + V_{ZERO} + V_{OFFSET} \quad (6)$$

Where:

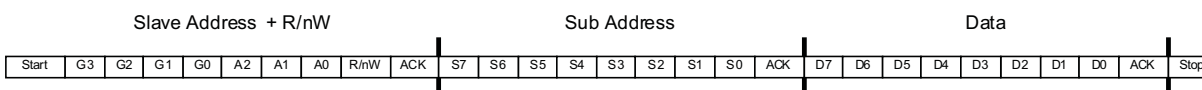
1.  $V_{SHUNT}$  is the output voltage of the current shunt monitor
2.  $V_{CSIN}$  is the charger side of the shunt resistor
3.  $V_{CSOUT}$  is the battery side of the shunt resistor
4.  $V_{ZERO}$  is the 0-current reference voltage
5.  $V_{OFFSET}$  is the offset of the differential amplifier

The offset of the differential amplifier introduces a measurement error of  $\pm 40 \mu V$  input referred, equivalent to  $\pm 2$  mA assuming a 20-m $\Omega$  shunt resistor which can be calibrated out by the system.

The shunt monitor is disabled by default and can be enabled by the host by setting the SMON\_EN bit in the CONTROL register to 1.

## I<sup>2</sup>C BUS OPERATION

The TPS65200 hosts a slave I<sup>2</sup>C interface that supports data rates up to 400 kbit/s and auto-increment addressing and is compliant to I<sup>2</sup>C standard 3.0.



**Figure 56. Subaddress in I<sup>2</sup>C Transmission**

Start – Start Condition

G(3:0) – Group ID: Address fixed at 1101

A(2:0) – Device Address: Address fixed at 010

R/nW – Read / not Write Select Bit

ACK – Acknowledge

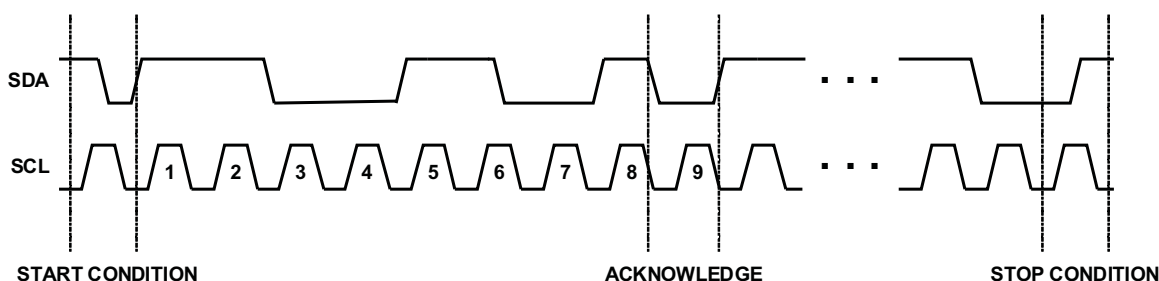
S(7:0) – Subaddress: defined per register map

D(7:0) – Data; Data to be loaded into the device

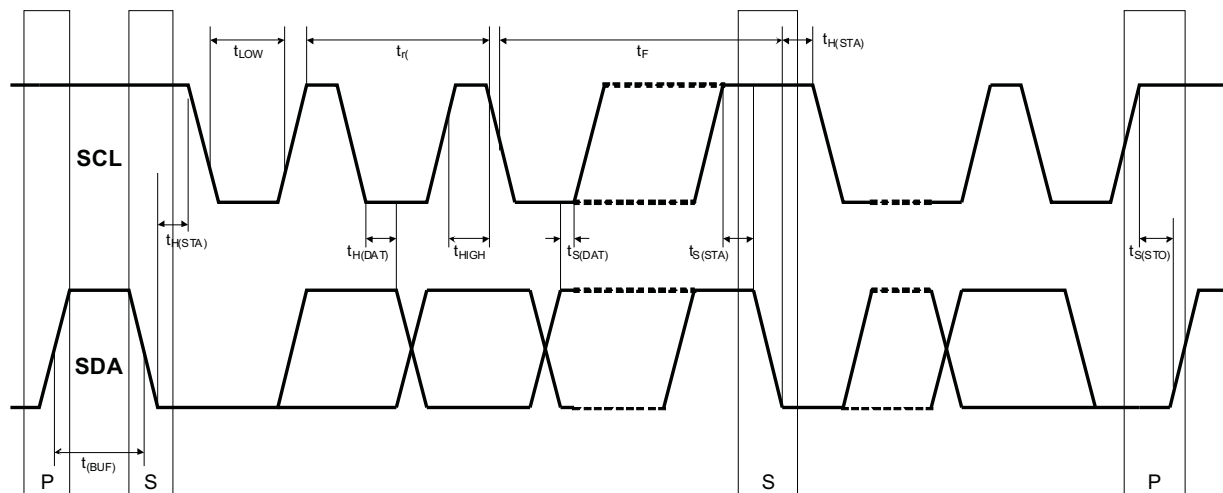
Stop – Stop Condition

The I<sup>2</sup>C bus is a communications link between a controller and a series of slave terminals. The link is established using a two-wired bus consisting of a serial clock signal (SCL) and a serial data signal (SDA). The serial clock is sourced from the controller in all cases where the serial data line is bi-directional for data communication between the controller and the slave terminals. Each device has an open drain output to transmit data on the serial data line. An external pull-up resistor must be placed on the serial data line to pull the drain output high during data transmission.

Data transmission is initiated with a start bit from the controller as shown in [Figure 57](#). The start condition is recognized when the SDA line transitions from high to low during the high portion of the SCL signal. Upon reception of a start bit, the device will receive serial data on the SDA input and check for valid address and control information. If the appropriate group and address bits are set for the device, then the device will issue an acknowledge pulse and prepare the receive subaddress data. Subaddress data is decoded and responded to as per the Register Map section of this document. Data transmission is completed by either the reception of a stop condition or the reception of the data word sent to the device. A stop condition is recognized as a low to high transition of the SDA input during the high portion of the SCL signal. All other transitions of the SDA line must occur during the low portion of the SCL signal. An acknowledge is issued after the reception of valid address, sub-address and data words. The I<sup>2</sup>C interface will auto-sequence through register addresses, so that multiple data words can be sent for a given I<sup>2</sup>C transmission.



**Figure 57. I<sup>2</sup>C Start/Stop/Acknowledge Protocol**



**Figure 58. I²C Data Transmission Timing**

## DATA TRANSMISSION TIMING

$V_{BAT} = 3.6 \pm 5\%$ ,  $T_A = 25^\circ\text{C}$ ,  $C_L = 100\text{ pF}$  (unless otherwise noted)

| PARAMETER                                                  | TEST CONDITIONS | MIN | TYP  | MAX        | UNIT          |
|------------------------------------------------------------|-----------------|-----|------|------------|---------------|
| $f_{(SCL)}$ Serial clock frequency                         |                 |     |      | 100<br>400 | KHz           |
| $t_{(BUF)}$ Bus free time between stop and start condition | SCL = 100 kHz   | 4.7 |      |            | $\mu\text{s}$ |
|                                                            | SCL = 400 kHz   | 1.3 |      |            |               |
| $t_{(SP)}$ Tolerable spike width on bus                    | SCL = 100 kHz   |     |      | 50         | ns            |
|                                                            | SCL = 400 kHz   |     |      |            |               |
| $t_{LOW}$ SCL low time                                     | SCL = 100 kHz   | 4.7 |      |            | $\mu\text{s}$ |
|                                                            | SCL = 400 kHz   | 1.3 |      |            |               |
| $t_{HIGH}$ SCL high time                                   | SCL = 100 kHz   | 4   |      |            | $\mu\text{s}$ |
|                                                            | SCL = 400 kHz   | 0.6 |      |            |               |
| $t_{S(DAT)}$ SDA $\rightarrow$ SCL setup time              | SCL = 100 kHz   | 250 |      |            | ns            |
|                                                            | SCL = 400 kHz   | 100 |      |            |               |
| $t_{S(STA)}$ Start condition setup time                    | SCL = 100 kHz   | 4.7 |      |            | $\mu\text{s}$ |
|                                                            | SCL = 400 kHz   | 0.6 |      |            |               |
| $t_{S(STO)}$ Stop condition setup time                     | SCL = 100 kHz   | 4   |      |            | $\mu\text{s}$ |
|                                                            | SCL = 400 kHz   | 0.6 |      |            |               |
| $t_{H(DAT)}$ SDA $\rightarrow$ SCL hold time               | SCL = 100 kHz   | 0   | 3.45 |            | $\mu\text{s}$ |
|                                                            | SCL = 400 kHz   | 0   | 0.9  |            |               |
| $t_{H(STA)}$ Start condition hold time                     | SCL = 100 kHz   | 4   |      |            | $\mu\text{s}$ |
|                                                            | SCL = 400 kHz   | 0.6 |      |            |               |
| $t_{r(SCL)}$ Rise time of SCL Signal                       | SCL = 100 kHz   |     |      | 1000       | ns            |
|                                                            | SCL = 400 kHz   |     |      | 300        |               |
| $t_{f(SCL)}$ Fall time of SCL Signal                       | SCL = 100 kHz   |     |      | 300        | ns            |
|                                                            | SCL = 400 kHz   |     |      | 300        |               |
| $t_{r(SDA)}$ Rise time of SDA Signal                       | SCL = 100 kHz   |     |      | 1000       | ns            |
|                                                            | SCL = 400 kHz   |     |      | 300        |               |

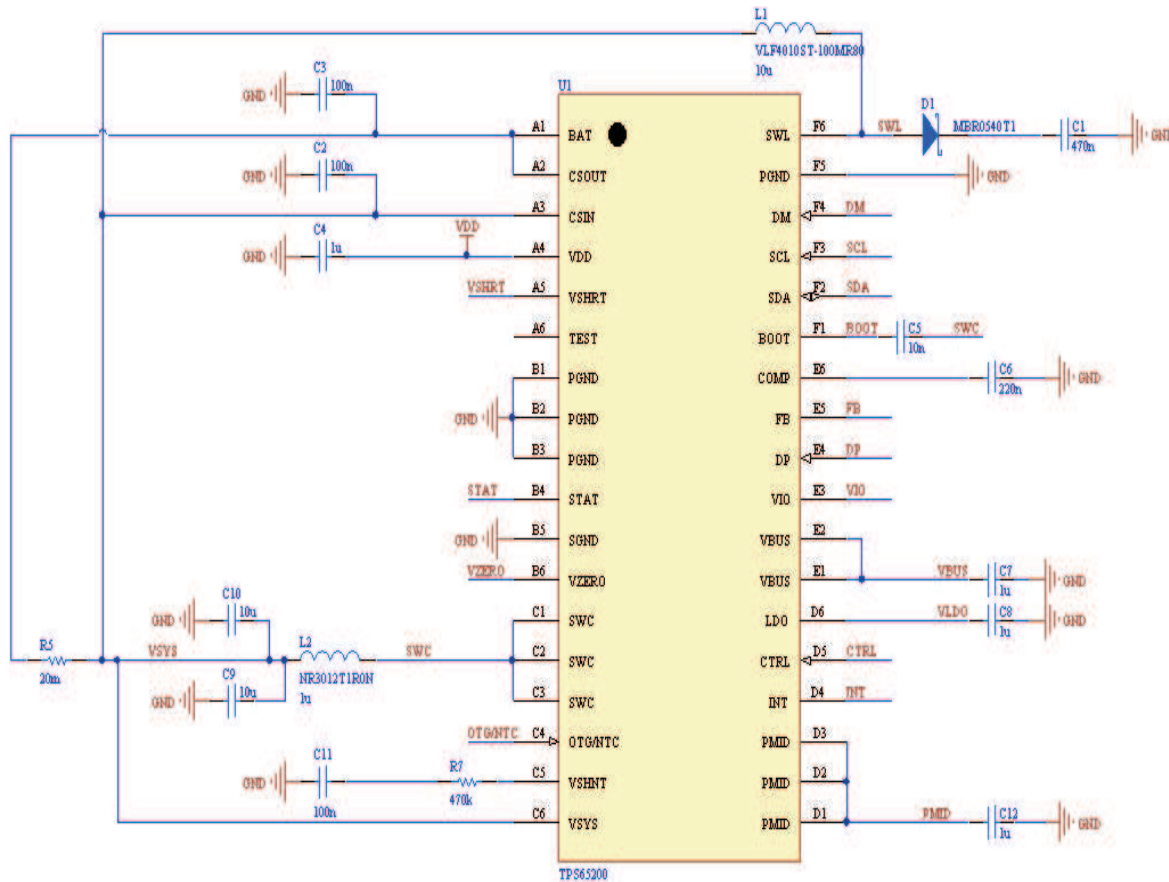
### DATA TRANSMISSION TIMING (continued)

$$V_{BAT} = 3.6 \pm 5\%, T_A = 25^\circ\text{C}, C_L = 100\text{ pF (unless otherwise noted)}$$

| PARAMETER            |                         | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|-------------------------|-----------------|-----|-----|-----|------|
| t <sub>f</sub> (SDA) | Fall time of SDA Signal | SCL = 100 KHz   |     |     | 300 | ns   |
|                      |                         | SCL = 400 kHz   |     |     | 300 |      |

## PCB LAYOUT CONSIDERATIONS

As for all switching power supplies, the layout is an important step in the design, especially at high peak currents and switching frequencies. If the layout is not carefully done, the DCDC converters might show noise problems and duty cycle jitter. The input capacitors on VBUS and PMID pins should be placed as close as possible to the input pins for good input voltage filtering. The inductors should be placed as close as possible to the switch pins to minimize the noise coupling into other circuits. The output capacitors need to be placed directly from the inductor (charger buck) or Schottky diode (WLED boost) to GND to minimize the ripple current in these traces. All ground pins need to be connected directly to the ground plane as should all passive components with ground connections. [Figure 59](#) and [Figure 60](#) show one example for placement and routing of the critical components on a four layer PCB. In this example all components are placed on the top layer and all routing is done on the top layer or bottom layer. Layer 2 is a solid ground plane and layer 3 is not used for layout. Please note that all IC pin connections are notes as [pin number]. E.g. The VSYS pin is referenced as [C6].



**I/O connections and WLED string are not shown.**

### Figure 59. Sample Schematic

Place C9 and C10 (VSYS) as close to L2 as possible with short connection to ground.

C4 should be placed close to the IC. Trace current is low (<1mA.)

Place C8 as close to the IC as possible. Max trace current is 60mA.

Keep C6-[E6] trace shielded from SWL node to avoid noise coupling.

Place C2 and C3 as close to the IC as possible. Connection C2-[A3] and C3-[A2] must not be in any current path and should be kept as short as possible. Traces should connect directly to sense resistor R5.

Pins [A1] and [A2] must not be shorted at the IC but routed separately to R5.

Keep [C1], [C2], [C3] (SWC) to L2

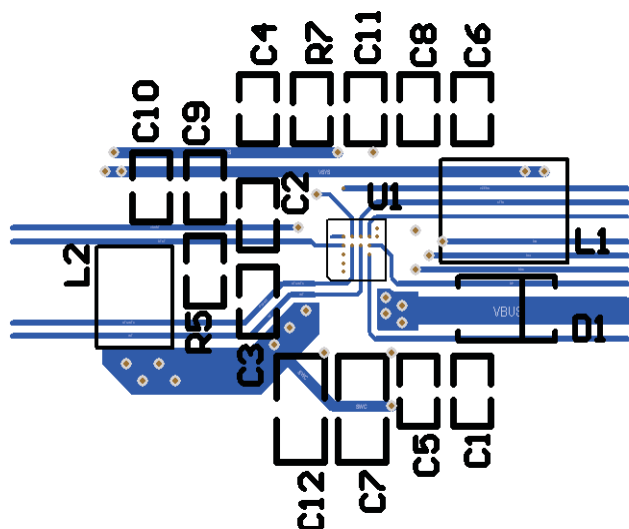
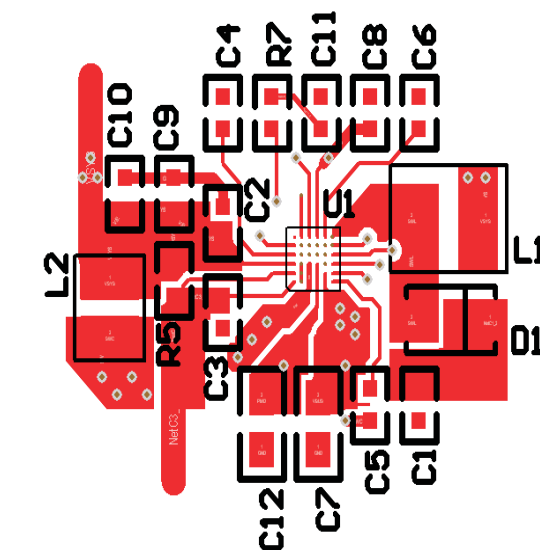
Keep [C1], [C2], [C3] (SWC) to L2 connection short and wide. Adding vias is OK. Max trace current is 2A.

Place C12 (PMID) as close to the IC as possible. Max trace current is

Place input capacitor C7 (VBUS) as close

Place C1 close to D1 and keep trace short and

Keep VSYS to L1 connection short and wide. Max trace current is 700mA.



**Figure 60. TOP: Top Layer PCB Layout. BOTTOM: Bottom Layer PCB Layout.**

**Table 1. REGISTER ADDRESS MAP**

| REGISTER | ADDRESS<br>(HEX) | NAME     | DEFAULT<br>VALUE | DESCRIPTION                    |
|----------|------------------|----------|------------------|--------------------------------|
| 0        | 0                | CONTROL  | 0000 1010        | Enable control register        |
| 1        | 1                | CONFIG_A | 0000 0001        | Charger current register       |
| 2        | 2                | CONFIG_B | 0001 1001        | Charger voltage register       |
| 3        | 3                | CONFIG_C | 1000 1010        | Special charger settings       |
| 4        | 4                | CONFIG_D | 0100 0000        | Charger safety limits settings |
| 5        | 5                | WLED     | 0001 1111        | WLED feedback voltage setting  |
| 6        | 6                | STATUS_A | 0100 0000        | Status register A              |
| 7        | 7                | STATUS_B | 0000 0001        | Status register B              |
| 8        | 8                | INT1     | 0000 0000        | Interrupt bits                 |
| 9        | 9                | INT2     | 0000 0000        | Interrupt bits (charger)       |
| 10       | 0A               | INT3     | 0000 0000        | Interrupt bits (boost)         |
| 11       | 0B               | MASK1    | 0000 0000        | Interrupt masking bits         |
| 12       | 0C               | MASK2    | 0000 0000        | Interrupt masking bits         |
| 13       | 0D               | MASK3    | 0000 0000        | Interrupt masking bits         |
| 14       | 0E               | CHIPID   | 0000 0000        | Chip ID register               |

## CONTROL REGISTER (CONTROL)

Address – 0x00h

| DATA BIT    | D7           | D6  | D5      | D4      | D3     | D2      | D1          | D0  |
|-------------|--------------|-----|---------|---------|--------|---------|-------------|-----|
| FIELD NAME  | STAT_EN[1:0] |     | SMON_EN | WLED_EN | LDO_EN | DPDM_EN | CH_EN [1:0] |     |
| READ/WRITE  | R/W          | R/W | R/W     | R/W     | R/W    | R/W     | R/W         | R/W |
| RESET VALUE | 0            | 0   | 0       | 0       | 1      | 0       | 1           | 0   |

| FIELD NAME   | BIT DEFINITION                                                                                                                           |
|--------------|------------------------------------------------------------------------------------------------------------------------------------------|
| STAT_EN[1:0] | STAT enable bits<br>00 – AUTO (controlled by charger status)<br>01 – ON (low impedance)<br>10 – OFF (high impedance)<br>11 – not defined |
| SMON_EN      | Shunt monitor enable bit<br>0 – Disabled<br>1 – Enabled                                                                                  |
| WLED_EN      | WLED enable bit<br>0 – Disabled<br>1 – Enabled<br>NOTE: WLED can also be enabled through CTRL pin.                                       |
| LDO_EN       | LDO enable bit<br>0 – Disabled<br>1 – Enabled                                                                                            |
| DPDM_EN      | D+/D- detection enable<br>0 – Disabled<br>1 – Enabled<br>NOTE: Bit is automatically reset after detection is completed.                  |
| CH_EN[1:0]   | Charger enable bits<br>00 – Disabled / HiZ mode<br>01 – Boost mode<br>10 – Charge<br>11 – Charge with automatic recharge                 |

**CHARGER CONFIG REGISTER A (CONFIG\_A)**

Address – 0x01h

| DATA BIT    | D7     | D6          | D5  | D4  | D3  | D2          | D1  | D0  |
|-------------|--------|-------------|-----|-----|-----|-------------|-----|-----|
| FIELD NAME  | LMTSEL | VICHRG[3:0] |     |     |     | VITERM[2:0] |     |     |
| READ/WRITE  | R/W    | R/W         | R/W | R/W | R/W | R/W         | R/W | R/W |
| RESET VALUE | 0      | 0           | 0   | 0   | 0   | 0           | 0   | 1   |

| FIELD NAME  | BIT DEFINITION <sup>(1)</sup>                                                                                                                                                                                                                                                                                                                                                                                       |
|-------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| LMTSEL      | Input Current Limit selection<br>0 – Input current limit is set to the higher of IIN_LIMIT[1:0] (CONFIG_B) and D+D- det. result<br>1 – IIN_LIMIT[1:0] (CONFIG_B) applied, D+D- detection result is ignored                                                                                                                                                                                                          |
| VICHRG[3:0] | Charge current sense voltage (current equivalent for 20 mΩ shunt)<br>0000 – 11 mV (550 mA)<br>0001 – 13 mV (650 mA)<br>0010 – 15 mV (75 mA)<br>0011 – 17 mV (850 mA)<br>0100 – 19 mV (950 mA)<br>0101 – 21 mV (105 mA)<br>0101 – 21 mV (1050 mA)<br>0110 – 23 mV (1150 mA)<br>0111 – 25 mV (1250 mA)<br>1000 – 27 mV (1350 mA)<br>1001 – 29 mV (1450 mA)<br>1010 – 31 mV (1550 mA)<br>...<br>1111 – 31 mV (1550 mA) |
| VITERM[2:0] | Termination current sense voltage (current equivalent for 20 mΩ shunt)<br>000 – 1 mV (50 mA)<br>001 – 2 mV (100 mA)<br>010 – 3 mV (150 mA)<br>011 – 4 mV (200 mA)<br>100 – 5 mV (250 mA)<br>101 – 6 mV (300 mA)<br>110 – 7 mV (350 mA)<br>111 – 8 mV (400 mA)                                                                                                                                                       |

(1) During charging the lower value of VMCHRG[3:0] (CONFIG\_D register) and VICHRG[2:0] applies.

## CHARGER CONFIG REGISTER B (CONFIG\_B)

Address – 0x02h

| DATA BIT    | D7             | D6  | D5         | D4  | D3  | D2  | D1  | D0  |
|-------------|----------------|-----|------------|-----|-----|-----|-----|-----|
| FIELD NAME  | IIN_LIMIT[1:0] |     | VOREG[5:0] |     |     |     |     |     |
| READ/WRITE  | R/W            | R/W | R/W        | R/W | R/W | R/W | R/W | R/W |
| RESET VALUE | 0              | 0   | 0          | 1   | 1   | 0   | 0   | 1   |

| FIELD NAME     | BIT DEFINITION <sup>(1)</sup>                                                                                                                                                                                                                                                                                  |
|----------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| IIN_LIMIT[1:0] | Input current limit setting<br>00 – 100 mA<br>01 – 500 mA<br>10 – 975 mA<br>11 – No input current limit                                                                                                                                                                                                        |
| VOREG[5:0]     | Battery regulation voltage / boost output voltage<br>00 0000 – 3.50 V / 4.425 V<br>00 0001 – 3.52 V / 4.448 V<br>00 0011 – 3.56 V / 4.471 V<br>...<br>01 1000 – 3.98 V / 4.077 V<br>01 1001 – 4.00 V / 5 V<br>01 1010 – 4.02 V / 5.023 V<br>...<br>10 1111 – 4.44 V / 5.5 V<br>...<br>11 1111 – 4.44 V / 5.5 V |

(1) During charging the lower value of VMREG[3:0] (CONFIG\_D register) and VOREG[5:0] applies.

**CHARGER CONFIG REGISTER C (CONFIG\_C)**

Address – 0x03h

| DATA BIT    | D7     | D6     | D5     | D4      | D3      | D2         | D1  | D0  |
|-------------|--------|--------|--------|---------|---------|------------|-----|-----|
| FIELD NAME  | VS_REF | OTG_PL | OTG_EN | TERM_EN | LOW_CHG | VSREG[2:0] |     |     |
| READ/WRITE  | R/W    | R/W    | R/W    | R/W     | R/W     | R/W        | R/W | R/W |
| RESET VALUE | 1      | 0      | 0      | 0       | 1       | 0          | 1   | 0   |

| FIELD NAME | BIT DEFINITION                                                                                                                                                       |
|------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| VS_REF     | VSHORT reference select<br>0 – Internal (2.1 V) reference<br>1 – Current source on VSHRT pin is enabled. Pin voltage is used as 0.5 x VSHORT threshold.              |
| OTG_PL     | OTG pin polarity<br>0 – Active low<br>1 – Active high                                                                                                                |
| OTG_EN     | OTG pin enable<br>0 – Pin is disabled<br>1 – Pin is enabled                                                                                                          |
| TERM_EN    | Charge termination enable<br>0 – Disabled<br>1 – Enabled                                                                                                             |
| LOW_CHG    | Low charge current enable bit (current equivalent for 20 mΩ shunt)<br>0 – Normal charge current sense voltage per register CONFIG_A<br>1 – 3 mV (150 mA)             |
| VSREG[2:0] | Input voltage DPM regulation voltage<br>000 – 4.20 V<br>001 – 4.28 V<br>010 – 4.36 V<br>011 – 4.44 V<br>100 – 4.52 V<br>101 – 4.60 V<br>110 – 4.68 V<br>111 – 4.76 V |

## CHARGER CONFIG REGISTER D (CONFIG\_D)

Address – 0x04h

| DATA BIT    | D7          | D6  | D5  | D4  | D3         | D2  | D1  | D0  |
|-------------|-------------|-----|-----|-----|------------|-----|-----|-----|
| FIELD NAME  | VMCHRG[3:0] |     |     |     | VMREG[3:0] |     |     |     |
| READ/WRITE  | R/W         | R/W | R/W | R/W | R/W        | R/W | R/W | R/W |
| RESET VALUE | 0           | 1   | 0   | 0   | 0          | 0   | 0   | 0   |

| FIELD NAME  | BIT DEFINITION <sup>(1)</sup>                                                                                                                                                                                                                                                                                                                                                                                                                                  |
|-------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| VMCHRG[3:0] | <p>Maximum charge current sense voltage (current equivalent for 20 mΩ shunt)</p> <p>0000 – 11 mV (550 mA)</p> <p>0001 – 13 mV (650 mA)</p> <p>0010 – 15 mV (750 mA)</p> <p>0011 – 17 mV (850 mA)</p> <p>0100 – 19 mV (950 mA)</p> <p>0101 – 21 mV (1050 mA)</p> <p>0110 – 23 mV (1150 mA)</p> <p>0111 – 25 mV (1250 mA)</p> <p>1000 – 27 mV (1350 mA)</p> <p>1001 – 29 mV (1450 mA)</p> <p>1010 – 31 mV (1550 mA)</p> <p>...</p> <p>1111 – 31 mV (1550 mA)</p> |
| VMREG[3:0]  | <p>Maximum battery regulation voltage</p> <p>0000 – 4.20 V</p> <p>0001 – 4.22 V</p> <p>0010 – 4.24 V</p> <p>...</p> <p>1100 – 4.44 V</p> <p>...</p> <p>1111 – 4.44 V</p>                                                                                                                                                                                                                                                                                       |

- (1) CONFIG\_D register is reset to its default value when  $V_{CSOUT}$  voltage drops below  $V_{SHORT}$  threshold (typ.2.05 V). After  $V_{CSOUT}$  recovers to  $V_{CSOUT} > V_{SHORT}$  CONFIG\_D register value can be changed by the host until one of the other registers is written to. Writing to any other register locks the CONFIG\_D register from subsequent writes. If CONFIG\_D is not the first register to be written after reset, the default values apply. During charging the lower value of VMCHRG[3:0] and VICHRG[2:0] (CONFIG\_A register), and VMREG[3:0] and VOREG[5:0] (CONFIG\_B register) apply.

**WLED CONTROL REGISTER (WLED)**

Address – 0x05h

| DATA BIT    | D7       | D6       | D5       | D4       | D3  | D2  | D1  | D0  |
|-------------|----------|----------|----------|----------|-----|-----|-----|-----|
| FIELD NAME  | Not used | Not used | Not used | VFB[4:0] |     |     |     |     |
| READ/WRITE  | R        | R        | R        | R/W      | R/W | R/W | R/W | R/W |
| RESET VALUE | 0        | 0        | 0        | 1        | 1   | 1   | 1   | 1   |

| FIELD NAME | BIT DEFINITION                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
|------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Not used   | N/A                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
| Not used   | N/A                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
| Not used   | N/A                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
| VFB[4:0]   | <p>WLED feedback voltage</p> <p>0 0000 – 0%</p> <p>0 0001 – 2.5%</p> <p>0 0010 – 4%</p> <p>0 0011 – 5.5%</p> <p>0 0100 – 7.5%</p> <p>0 0101 – 8.5%</p> <p>0 0110 – 10%</p> <p>0 0111 – 11.5%</p> <p>0 1000 – 13%</p> <p>0 1001 – 14.5%</p> <p>0 1010 – 16%</p> <p>0 1011 – 17.5%</p> <p>0 1100 – 19%</p> <p>0 1101 – 22%</p> <p>0 1110 – 25%</p> <p>0 1111 – 28%</p> <p>1 0000 – 31%</p> <p>1 0001 – 34%</p> <p>1 0010 – 37%</p> <p>1 0011 – 40%</p> <p>1 0100 – 43%</p> <p>1 0101 – 46%</p> <p>1 0110 – 49%</p> <p>1 0111 – 52%</p> <p>1 1000 – 58%</p> <p>1 1001 – 64%</p> <p>1 1010 – 70%</p> <p>1 1011 – 76%</p> <p>1 1100 – 82%</p> <p>1 1101 – 88%</p> <p>1 1110 – 94%</p> <p>1 1111 – 100%</p> |

## STATUS REGISTER A (STATUS\_A)

Address – 0x06h

| DATA BIT    | D7       | D6      | D5      | D4           | D3 | D2 | D1  | D0   |
|-------------|----------|---------|---------|--------------|----|----|-----|------|
| FIELD NAME  | Not used | STANDBY | MONITOR | CHSTAT [2:0] |    |    | LDO | WLED |
| READ/WRITE  | R        | R       | R       | R            | R  | R  | R   | R    |
| RESET VALUE | 0        | 1       | 0       | 0            | 0  | 0  | 0   | 0    |

| FIELD NAME   | BIT DEFINITION <sup>(1)</sup>                                                                                                                                                                                                              |
|--------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Not used     | N/A                                                                                                                                                                                                                                        |
| STANDBY      | Standby status indicator<br>0 – Device is in ACTIVE mode<br>1 – Device is in STANDBY mode                                                                                                                                                  |
| MONITOR      | Current shunt monitor status indicator<br>0 – Current shunt monitor is disabled<br>1 – Current shunt monitor is enabled                                                                                                                    |
| CHSTAT [2:0] | Charger status bit<br>000 – High impedance mode<br>001 – Charge in progress (fast charge)<br>010 – Charge done<br>011 – Boost mode<br>100 – Charge in progress (pre charge)<br>101 – Not defined<br>110 – Not defined<br>111 – Not defined |
| LDO          | LDO status bit<br>0 – LDO is disabled (OFF)<br>1 – LDO is enabled (ON), no fault                                                                                                                                                           |
| WLED         | WLED status bit<br>0 – WLED disabled (OFF)<br>1 – WLED enabled                                                                                                                                                                             |

(1) Default values reflect state after Power-ON Reset, no charger plugged in, no faults present.

## STATUS REGISTER B (STATUS\_B)

Address – 0x07h

| DATA BIT    | D7    | D6       | D5       | D4       | D3       | D2     | D1     | D0  |
|-------------|-------|----------|----------|----------|----------|--------|--------|-----|
| FIELD NAME  | RESET | Not used | Not used | Not used | Not used | DPDM_D | DPDM_R | OTG |
| READ/WRITE  | W     | R        | R        | R        | R        | R      | R      | R   |
| RESET VALUE | 0     | 0        | 0        | 0        | 0        | 0      | 0      | 1   |

| FIELD NAME | BIT DEFINITION <sup>(1)</sup>                                                                                                            |
|------------|------------------------------------------------------------------------------------------------------------------------------------------|
| RESET      | Reset<br>0 – No effect<br>1 – Reset all parameters to default values<br>NOTE: Read always returns “0”                                    |
| Not used   | N/A                                                                                                                                      |
| Not used   | N/A                                                                                                                                      |
| Not used   | N/A                                                                                                                                      |
| Not used   | N/A                                                                                                                                      |
| DPDM_D     | D+/D- detection done bit<br>0 – DPDM detection in progress or not started after initial power-up reset<br>1 – DPDM detection is complete |
| DPDM_R     | D+D- detection result<br>0 – Standard USB port (500-mA current limit)<br>1 – USB charger (1000-mA current limit)                         |
| OTG        | OTG pin status<br>0 – OTG pin at low level<br>1 – OTG pin at high level                                                                  |

(1) Default values reflect state after Power-ON Reset, no charger plugged in, no faults present, OTG pin high..

## INTERRUPT REGISTER 1 (INT1)

Address – 0x08h

| DATA BIT    | D7   | D6       | D5       | D4                    | D3                    | D2                    | D1                    | D0    |
|-------------|------|----------|----------|-----------------------|-----------------------|-----------------------|-----------------------|-------|
| FIELD NAME  | TSDI | VBUSOVPI | Not used | Not used/<br>Reserved | Not used/<br>Reserved | Not used/<br>Reserved | Not used/<br>Reserved | WLEDI |
| READ/WRITE  | R    | R        | R        | R/W                   | R/W                   | R/W                   | R/W                   | R     |
| RESET VALUE | 0    | 0        | 0        | 0                     | 0                     | 0                     | 0                     | 0     |

| FIELD NAME          | BIT DEFINITION                                                                                                                                   |
|---------------------|--------------------------------------------------------------------------------------------------------------------------------------------------|
| TSDI                | Thermal shutdown fault. Set if die temperature exceeds thermal shutdown threshold. Reset when die temperature drops below TSD release threshold. |
| VBUSOVPI            | VBUS over voltage protection. Set when $V_{BUS} > V_{OVP-IN\_USB}$ is detected.                                                                  |
| Not used            | N/A                                                                                                                                              |
| Not used / Reserved | N/A / Reserved                                                                                                                                   |
| Not used / Reserved | N/A / Reserved                                                                                                                                   |
| Not used / Reserved | N/A / Reserved                                                                                                                                   |
| Not used / Reserved | N/A / Reserved                                                                                                                                   |
| WLEDI               | WLED driver over voltage                                                                                                                         |

## INTERRUPT REGISTER 2 (INT2)

Address – 0x09h

| DATA BIT    | D7     | D6     | D5           | D4      | D3      | D2     | D1      | D0     |
|-------------|--------|--------|--------------|---------|---------|--------|---------|--------|
| FIELD NAME  | CHRVPI | CHBADI | CHBATOV<br>I | CHTERMI | CHRGHGI | CH32MI | CHTREGI | CHDPMI |
| READ/WRITE  | R      | R      | R            | R       | R       | R      | R       | R      |
| RESET VALUE | 0      | 0      | 0            | 0       | 0       | 0      | 0       | 0      |

| FIELD NAME | BIT DEFINITION <sup>(1)</sup>                                                                         |
|------------|-------------------------------------------------------------------------------------------------------|
| CHRVPI     | Charger fault. Reverse protection ( $V_{VBUS} > V_{IN(MIN)}$ and $V_{VBUS} < V_{CSOUT+VREV}$ (fault)) |
| CHBADI     | Charger fault. Bad adaptor ( $V_{BUS} < V_{IN(MIN)}$ )                                                |
| CHBATOVI   | Charger fault. Battery OVP                                                                            |
| CHTERMI    | Charge terminated                                                                                     |
| CHRGHGI    | Recharge request ( $V_{CSOUT} < V_{OREG} - VRCH$ )                                                    |
| CH32MI     | Charger fault. 32 m time-out (fault)                                                                  |
| CHTREGI    | Charger warning. Thermal regulation loop active.                                                      |
| CHDPMI     | Charger warning. Input voltage DPM loop active.                                                       |

(1) All charger faults result in disabling the charger (CH\_EN[1:0] = 00). Recharge request disables the charger only if CH\_EN[1:0] = 10.

## INTERRUPT REGISTER 3 (INT3)

Address – 0x0Ah

| DATA BIT    | D7            | D6     | D5           | D4        | D3      | D2       | D1       | D0       |
|-------------|---------------|--------|--------------|-----------|---------|----------|----------|----------|
| FIELD NAME  | BSTBUSO<br>VI | BSTOLI | BSTLOWV<br>I | BSTBATOVI | BST32SI | Not used | Not used | Not used |
| READ/WRITE  | R             | R      | R            | R         | R       | R        | R        | R        |
| RESET VALUE | 0             | 0      | 0            | 0         | 0       | 0        | 0        | 0        |

| FIELD NAME | BIT DEFINITION <sup>(1)</sup>                    |
|------------|--------------------------------------------------|
| BSTBUSOVI  | Boost fault. VBUS OVP ( $V_{BUS} > V_{BUSOVP}$ ) |
| BSTOLI     | Boost fault. Over load.                          |
| BSTLOWVI   | Boost fault. Battery voltage is too low.         |
| BSTBATOVI  | Boost fault. Battery over voltage.               |
| BST32SI    | Boost fault. 32-s time-out fault.                |
| Not used   | N/A                                              |
| Not used   | N/A                                              |
| Not used   | N/A                                              |

(1) All BOOST faults result in disabling the boost converter (CH\_EN[1:0] = 00).

**INTERRUPT MASK REGISTER 1 (MASK1)**

Address – 0x0Bh

| DATA BIT    | D7   | D6           | D5       | D4       | D3       | D2       | D1       | D0    |
|-------------|------|--------------|----------|----------|----------|----------|----------|-------|
| FIELD NAME  | TSDM | VBUSOV<br>PM | Not used | Not used | Not used | Not used | Not used | WLEDM |
| READ/WRITE  | R/W  | R/W          | R/W      | R/W      | R/W      | R/W      | R/W      | R/W   |
| RESET VALUE | 0    | 0            | 0        | 0        | 0        | 0        | 0        | 0     |

| FIELD NAME | BIT DEFINITION <sup>(1)</sup>                                                     |
|------------|-----------------------------------------------------------------------------------|
| TSDM       | TSD fault interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked      |
| VBUSOVPM   | VBUS OVP fault interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked |
| Not used   | N/A                                                                               |
| Not used   | N/A                                                                               |
| Not used   | N/A                                                                               |
| Not used   | N/A                                                                               |
| Not used   | N/A                                                                               |
| WLEDM      | WLED fault interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked     |

(1) Setting any of the interrupt mask bits does not disable protection circuits. When set, the respective fault will not be signaled on the INT pin.

## INTERRUPT MASK REGISTER 2 (MASK2)

Address – 0x0Ch

| DATA BIT    | D7     | D6     | D5           | D4      | D3      | D2     | D1      | D0     |
|-------------|--------|--------|--------------|---------|---------|--------|---------|--------|
| FIELD NAME  | CHRVPM | CHBADM | CHBATOV<br>M | CHTERMM | CHRCHGM | CH32MM | CHTREGM | CHDPMM |
| READ/WRITE  | R/W    | R/W    | R/W          | R/W     | R/W     | R/W    | R/W     | R/W    |
| RESET VALUE | 0      | 0      | 0            | 0       | 0       | 0      | 0       | 0      |

| FIELD NAME   | BIT DEFINITION <sup>(1)</sup>                                                                             |
|--------------|-----------------------------------------------------------------------------------------------------------|
| CHRVPM       | Charger reverse protection interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked             |
| CHBADM       | Charger Bad adaptor interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked                    |
| CHBATOV<br>M | Charger battery overvoltage interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked            |
| CHTERMM      | Charge terminated interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked                      |
| CHRCHGM      | Charger recharge request interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked               |
| CH32MM       | Charger 32m timeout interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked                    |
| CHTREGM      | Charger thermal regulation loop active interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked |
| CHDPMM       | Charger input current DPM active interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked       |

- (1) Setting any of the interrupt mask bits does not disable protection circuits. When set, the respective fault will not be signaled on the INT pin

**INTERRUPT MASK REGISTER 3 (MASK3)**

Address – 0x0Dh

| DATA BIT    | D7            | D6     | D5           | D4        | D3      | D2       | D1       | D0       |
|-------------|---------------|--------|--------------|-----------|---------|----------|----------|----------|
| FIELD NAME  | BSTBUSOV<br>M | BSTOLM | BSTLOWV<br>M | BSTBATOVM | BST32SM | Not used | Not used | Not used |
| READ/WRITE  | R/W           | R/W    | R/W          | R/W       | R/W     | R/W      | R/W      | R/W      |
| RESET VALUE | 0             | 0      | 0            | 0         | 0       | 0        | 0        | 0        |

| FIELD NAME | BIT DEFINITION <sup>(1)</sup>                                                                 |
|------------|-----------------------------------------------------------------------------------------------|
| BSTBUSOVM  | Boost VBUS overvoltage interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked     |
| BSTOLM     | Boost over load interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked            |
| BSTLOWVM   | Boost low battery voltage interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked  |
| BSTBATOVM  | Boost battery over voltage interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked |
| BST32SM    | Boost 32s time out interrupt mask<br>0 – Interrupt not masked<br>1 – Interrupt masked         |
| Not used   | N/A                                                                                           |
| Not used   | N/A                                                                                           |
| Not used   | N/A                                                                                           |

(1) Setting any of the interrupt mask bits does not disable protection circuits. When set, the respective fault will not be signaled on the INT pin.

## CHIP ID REGISTER (CHIPID)

Address – 0x0Eh

| DATA BIT    | D7          | D6 | D5        | D4 | D3 | D2       | D1 | D0               |
|-------------|-------------|----|-----------|----|----|----------|----|------------------|
| FIELD NAME  | VENDOR[1:0] |    | CHIP[2:0] |    |    | REV[2:0] |    |                  |
| READ/WRITE  | R           | R  | R         | R  | R  | R        | R  | R                |
| RESET VALUE | 0           | 0  | 0         | 0  | 0  | 0        | 0  | 1 <sup>(1)</sup> |

(1) Device dependent.

| FIELD NAME  | BIT DEFINITION                                                                                           |
|-------------|----------------------------------------------------------------------------------------------------------|
| VENDOR[1:0] | Vendor code 00 – default<br>00 – Default                                                                 |
| CHIP[2:0]   | Chip ID<br>000 – TPS65200<br>001 – Future use<br>...<br>111 – Future use                                 |
| REV[2:0]    | Revision code<br>000 – Revision 1.0<br>001 – Revision 1.1<br>010 – Future use<br>...<br>111 – Future use |

**PACKAGING INFORMATION**

| Orderable Device | Status <sup>(1)</sup> | Package Type | Package Drawing | Pins | Package Qty | Eco Plan <sup>(2)</sup>    | Lead/<br>Ball Finish | MSL Peak Temp <sup>(3)</sup> | Samples<br>(Requires Login) |
|------------------|-----------------------|--------------|-----------------|------|-------------|----------------------------|----------------------|------------------------------|-----------------------------|
| TPS65200YFFR     | ACTIVE                | DSBGA        | YFF             | 36   | 3000        | Green (RoHS<br>& no Sb/Br) | Call TI              | Level-1-260C-UNLIM           |                             |
| TPS65200YFFT     | ACTIVE                | DSBGA        | YFF             | 36   | 250         | Green (RoHS<br>& no Sb/Br) | Call TI              | Level-1-260C-UNLIM           |                             |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

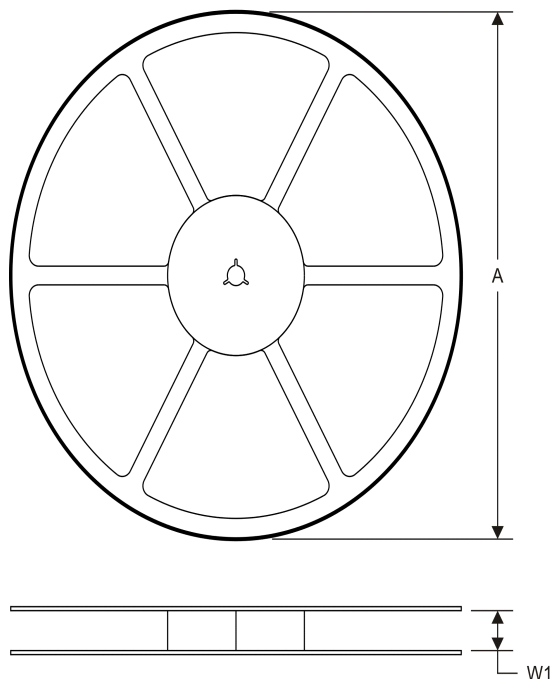
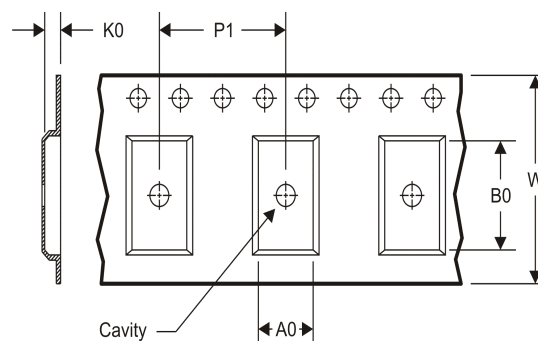
**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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**TAPE AND REEL INFORMATION**
**REEL DIMENSIONS**

**TAPE DIMENSIONS**


|    |                                                           |
|----|-----------------------------------------------------------|
| A0 | Dimension designed to accommodate the component width     |
| B0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

**TAPE AND REEL INFORMATION**

\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS65200YFFR | DSBGA        | YFF             | 36   | 3000 | 180.0              | 8.4                | 2.76    | 3.02    | 0.83    | 4.0     | 8.0    | Q2            |
| TPS65200YFFT | DSBGA        | YFF             | 36   | 250  | 180.0              | 8.4                | 2.76    | 3.02    | 0.83    | 4.0     | 8.0    | Q2            |

## TAPE AND REEL BOX DIMENSIONS

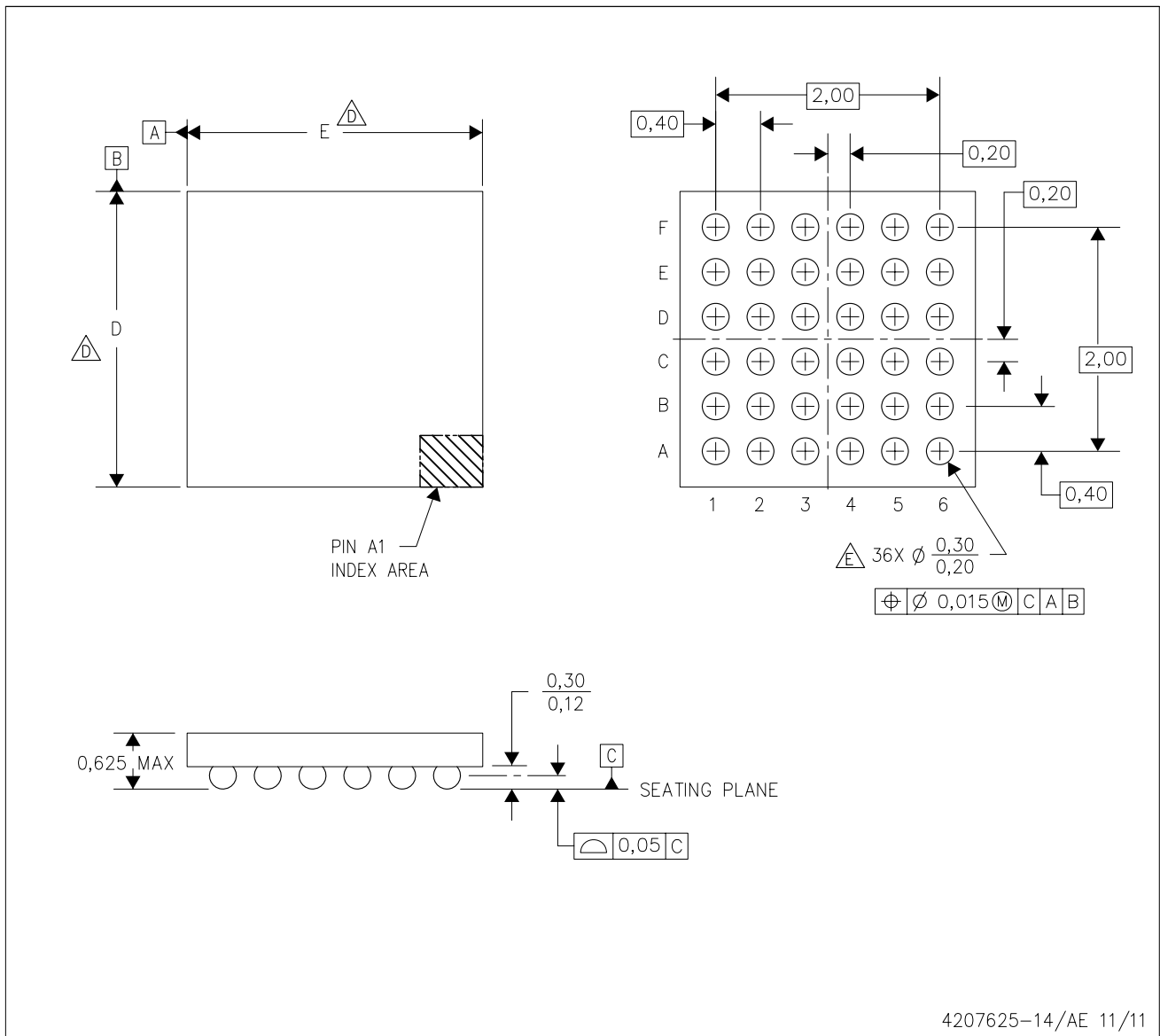


\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS65200YFFR | DSBGA        | YFF             | 36   | 3000 | 210.0       | 185.0      | 35.0        |
| TPS65200YFFT | DSBGA        | YFF             | 36   | 250  | 210.0       | 185.0      | 35.0        |

YFF (S-XBGA-N36)

DIE-SIZE BALL GRID ARRAY



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. NanoFree™ package configuration.
  - The package size (Dimension D and E) of a particular device is specified in the device Product Data Sheet version of this drawing, in case it cannot be found in the product data sheet please contact a local TI representative.
  - E. Reference Product Data Sheet for array population.  
6 x 6 matrix pattern is shown for illustration only.
  - F. This package contains Pb-free balls.

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